

# Synchronous Step-Down PWM Controller

## ISL8117A

The [ISL8117A](#) is a synchronous buck controller to generate POL voltage rails and bias voltage rails for a wide variety of applications in industrial and general purpose segments. Its wide input and output voltage ranges make it suitable for telecommunication and after-market automotive applications. ISL8117A is a derivative from the ISL8117 by replacing its CLKOUT pin with COMP pin to provide flexibility to customers to configure the voltage loop compensation externally.

The ISL8117A uses the valley current modulation technique to bring a hassle-free power supply design with minimal number of components and complete protection from unwanted events.

The ISL8117A offers programmable soft-start and enable functions along with a power-good indicator for ease of supply rail sequencing and other housekeeping requirements. In ideal situations, a complete power supply circuit can be designed with 10 external components and provide OV/OC/OT protections in a space conscious 16 Ld 4mmx4mm QFN package. The package uses an EPAD to improve thermal dissipation and noise immunity. Low pin count, less number of external components and default internal values, makes the ISL8117A an ideal solution for quick to market simple power supply designs. The ISL8117A utilizes single resistor settings for other functions such as operating frequency and overcurrent protection. Its current mode control with  $V_{IN}$  feed-forward enables it to cover various applications. The unique DEM/Skipping mode at light load dramatically lowers standby power consumption with consistent output ripple over different load levels.

## Related Literature

- UG049, "ISL8117AEVAL1Z Evaluation Board User Guide"
- UG050, "ISL8117AEVAL2Z Evaluation Board User Guide"

## Features

- Wide input voltage range: 4.5V to 60V
- Wide output voltage range: 0.6V to 54V
- Light-load efficiency enhancement
  - Low ripple diode emulation mode with pulse skipping
- Programmable soft-start
- Supports prebiased output with SR soft-start
- Programmable frequency: 100kHz to 2MHz
- External sync
- PGOOD indicator
- Forced PWM
- Adaptive shoot-through protection
- No external current sense resistor
  - Use lower MOSFET  $r_{DS(ON)}$
- Functional pins with default design values
  - EN, RT, SS/TRK, MOD/SYNC, LGATE/OCS
- Complete protection
  - Overcurrent, overvoltage, over-temperature, undervoltage
- Pb-free (RoHS compliant)

## Applications

- PLC and factory automation
- Industrial equipments
- Security surveillance
- Server and data centers
- Switcher and routers
- Telecom and datacom
- LED panels

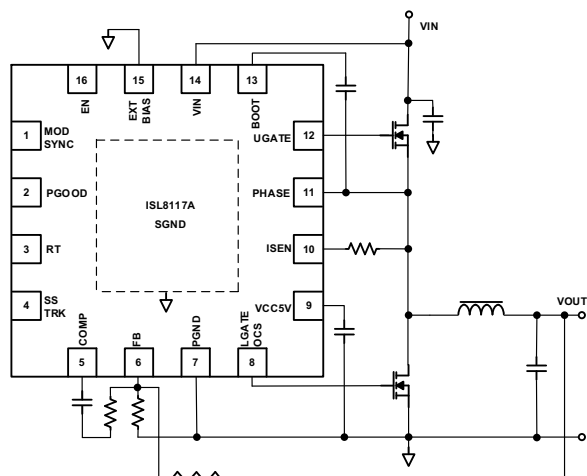


FIGURE 1. TYPICAL APPLICATION

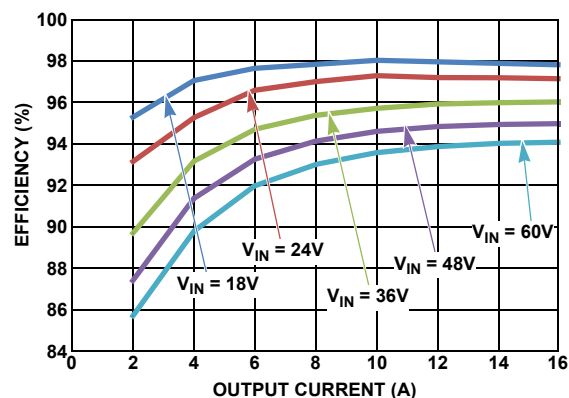


FIGURE 2. EFFICIENCY

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## Ordering Information

| PART NUMBER<br>(Notes 1, 2, 3) | PART MARKING                | TEMP. RANGE<br>(°C) | PACKAGE<br>(RoHS Compliant) | PKG.<br>DWG. # |
|--------------------------------|-----------------------------|---------------------|-----------------------------|----------------|
| ISL8117AFRZ                    | 81 17AFRZ                   | -40 to +125         | 16 Ld 4x4 QFN               | L16.4x4A       |
| ISL8117AEVAL1Z                 | High Power Evaluation Board |                     |                             |                |
| ISL8117AEVAL2Z                 | Low Power Evaluation Board  |                     |                             |                |

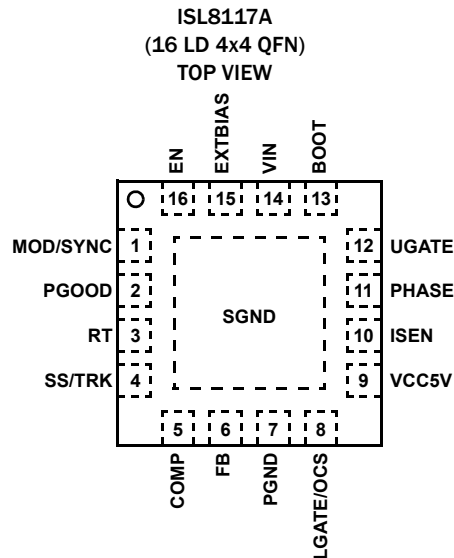
### NOTES:

1. Add "-T\*" suffix for tape and reel. Please refer to [TB347](#) for details on reel specifications.
2. These Intersil Pb-free plastic packaged products employ special Pb-free material sets, molding compounds/die attach materials and 100% matte tin plate plus anneal (e3 termination finish, which is RoHS compliant and compatible with both SnPb and Pb-free soldering operations). Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.
3. For Moisture Sensitivity Level (MSL), please see device information page for [ISL8117A](#). For more information on MSL please see techbrief [TB363](#).

TABLE 1. TABLE OF KEY DIFFERENCES

| PART NUMBER | LOOP COMPENSATION                      | CLOCK OUTPUT SIGNAL               | PACKAGE                     |
|-------------|----------------------------------------|-----------------------------------|-----------------------------|
| ISL8117     | Internal compensation without COMP pin | Clock Output Signal on CLKOUT pin | 16 Ld 4x4 QFN ,16 Ld HTSSOP |
| ISL8117A    | External compensation with COMP pin    | No clock output signal            | 16 Ld 4x4 QFN               |

## Pin Configuration



## Pin Descriptions

| PIN NUMBER | PIN NAME | FUNCTION                                                                                                                                                                                                                                                                                                                                                        |
|------------|----------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 1          | MOD/SYNC | Dual function pin. Connect this pin to VCC5V to select diode emulation mode with pulse skipping at light load. While connected to ground or floating, the controller operates in PWM mode at light load. Connect this pin to an external clock for synchronization. The controller operates in PWM Mode at light load when synchronized with an external clock. |
| 2          | PGOOD    | Open-drain logic output used to indicate the status of output voltage. This pin is pulled down when the output is not within $\pm 12.5\%$ of the nominal voltage or the EN pin is pulled LOW.                                                                                                                                                                   |

## Pin Descriptions (Continued)

| PIN NUMBER | PIN NAME     | FUNCTION                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                    |
|------------|--------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 3          | RT           | <p>A resistor from this pin to ground adjusts the switching frequency from 100kHz to 2MHz. The switching frequency of the PWM controller is determined by the resistor, <math>R_T</math> as shown in <a href="#">Equation 1</a>.</p> $R_T = \left( \frac{39.2}{f_{SW}} - 1.96 \right) \cdot k\Omega \quad (\text{EQ. 1})$ <p>Where <math>f_{SW}</math> is the switching frequency in MHz.<br/>           When this pin is tied to ground, the output frequency is set to 300kHz.<br/>           When this pin is tied to VCC5V or floating, the output frequency is set to 600kHz.</p>                                      |
| 4          | SS/TRK       | <p>Dual function pin. When used for soft-starting control, a soft-start capacitor is connected from this pin to ground. A regulated 2μA soft-starting current charges up the soft-start capacitor. Value of the soft-start capacitor sets the output voltage ramp.</p> <p>When used for tracking control, an external supply rail is configured as the master and the output voltage of the master supply is applied to this pin via a resistor divider. The output voltage will track the master supply voltage.</p>                                                                                                       |
| 5          | COMP         | Voltage error amplifier output. It sets the reference of the inner current loop. Feedback compensation network is connected between the COMP and FB pins. The COMP pin can provide max 30mA source and sink current. When COMP pin is pulled below 1V, UGATE duty cycle reduces to 0%.                                                                                                                                                                                                                                                                                                                                      |
| 6          | FB           | Output feedback input. Connect FB to a resistive voltage divider from the output to SGND to adjust the output voltage.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      |
| 7          | PGND         | Power ground connection. This pin should be connected to the sources of the lower MOSFETs and the (-) terminals of the external input capacitors.                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |
| 8          | LGATE/OCS    | Low-side MOSFET gate driver output and OC set pin. Connect a 1k to 30k resistor between this pin and ground to set the overcurrent threshold. If there is no resistor connected from this pin to GND, the overcurrent threshold is automatically set to the same point as a 10k resistor does.                                                                                                                                                                                                                                                                                                                              |
| 9          | VCC5V        | Output of the internal 5V linear regulator. This output supplies bias for the IC, the low-side gate driver and the internal boot circuitry for the high-side gate driver. The VCC5V pin must always be decoupled to power ground with a minimum of 4.7μF ceramic capacitor placed very close to the pin. Do not allow the voltage at VCC5V to exceed VIN at any time. To prevent excessive current through the VCC5V pin to the VIN pin, a resistor can be connected from the VIN pin to the power supply.                                                                                                                  |
| 10         | ISEN         | Current sense signal input. This pin is used to monitor the voltage drop across the lower MOSFET for current loop feedback and overcurrent protection.                                                                                                                                                                                                                                                                                                                                                                                                                                                                      |
| 11         | PHASE        | Phase node connection. This pin is connected to the junction of the upper MOSFET's source, output filter inductor and lower MOSFET's drain.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                 |
| 12         | UGATE        | High-side MOSFET gate driver output.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                        |
| 13         | BOOT         | Bootstrap pin to provide bias for high-side driver. The positive terminal of the bootstrap capacitor connects to this pin. The bootstrap diode is integrated to help reduce total cost and reduce layout complexity.                                                                                                                                                                                                                                                                                                                                                                                                        |
| 14         | VIN          | This pin should be tied to the input rail. It provides power to the internal linear drive circuitry and is also used by the feed-forward controller to adjust the amplitude of the PWM sawtooth. Decouple this pin with a small ceramic capacitor (0.1μF to 1μF) to ground.                                                                                                                                                                                                                                                                                                                                                 |
| 15         | EXTBIAS      | <p>Input from an optional external 5V bias supply. There is an internal switch from this pin to VCC5V. This switch closes and supplies the IC power, bypassing the internal linear regulator, when voltage at EXTBIAS is higher than 4.7V (typ). Do not allow voltage at the EXTBIAS pin to exceed VIN at any time. To prevent excessive current through the EXTBIAS pin to the VIN pin, a resistor can be connected from the VIN pin to the power supply.</p> <p>Decouple this pin to ground with a small ceramic capacitor (0.1μF to 1μF) when it is in use, otherwise tie this pin to ground. DO NOT float this pin.</p> |
| 16         | EN           | This pin provides an enable/disable function. The output is disabled when the pin is pulled to ground. When the voltage on the pin reaches 1.6V, the output becomes active. When the pin is floating, it will be enabled in default by internal pull-up.                                                                                                                                                                                                                                                                                                                                                                    |
| -          | SGND<br>EPAD | <p>This is the small-signal ground common to all control circuitry. It is suggested to route this separately from the high current ground (PGND). SGND and PGND can be tied together if there is one solid ground plane with no noisy currents around the chip. All voltage levels are measured with respect to this pin.</p> <p>EPAD at ground potential. EPAD is connected to SGND internally. However, it is highly recommended to solder it directly to ground plane for better thermal performance and noise immunity.</p>                                                                                             |

## Block Diagram

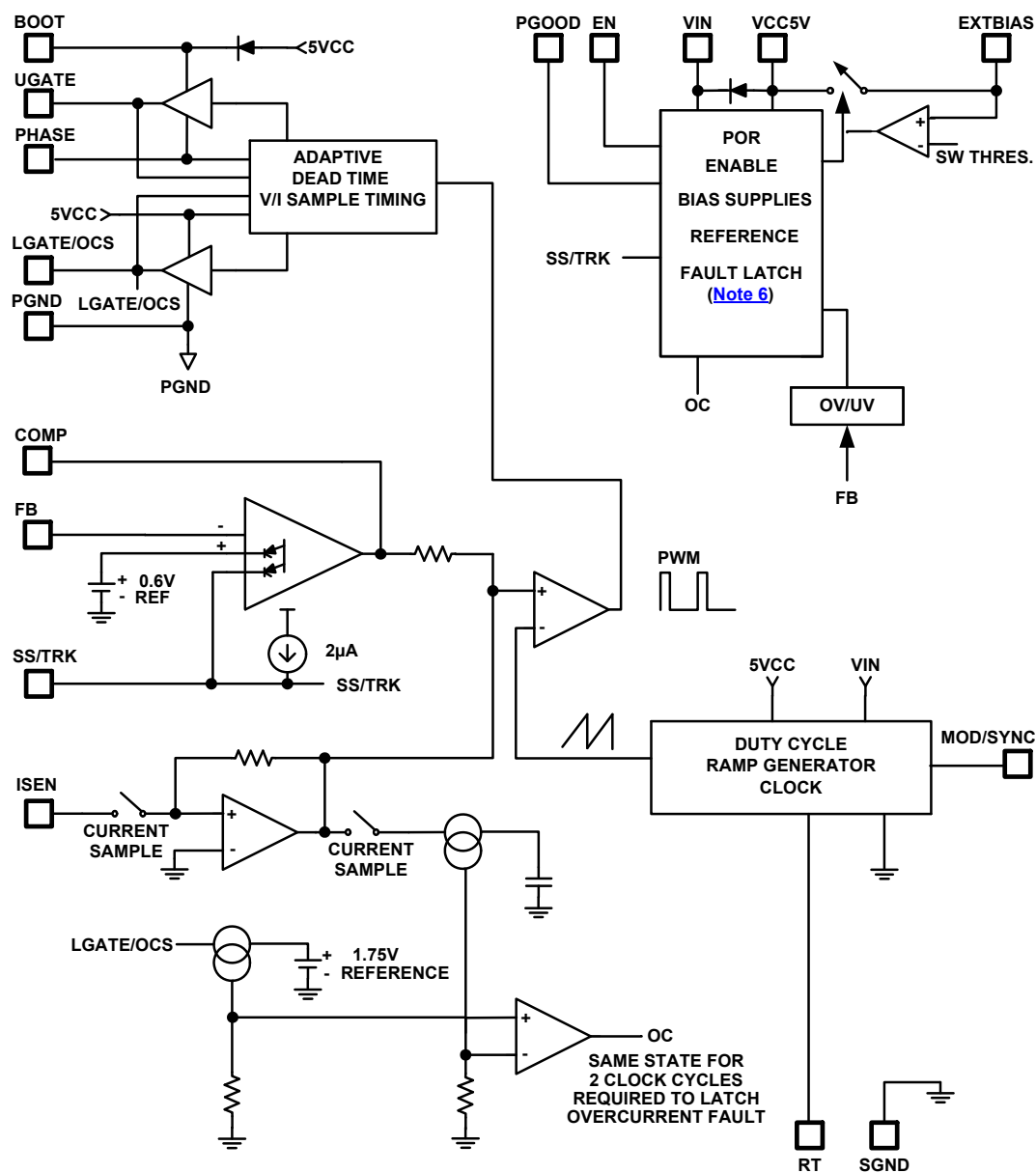


FIGURE 3. BLOCK DIAGRAM

## Typical Application Schematics

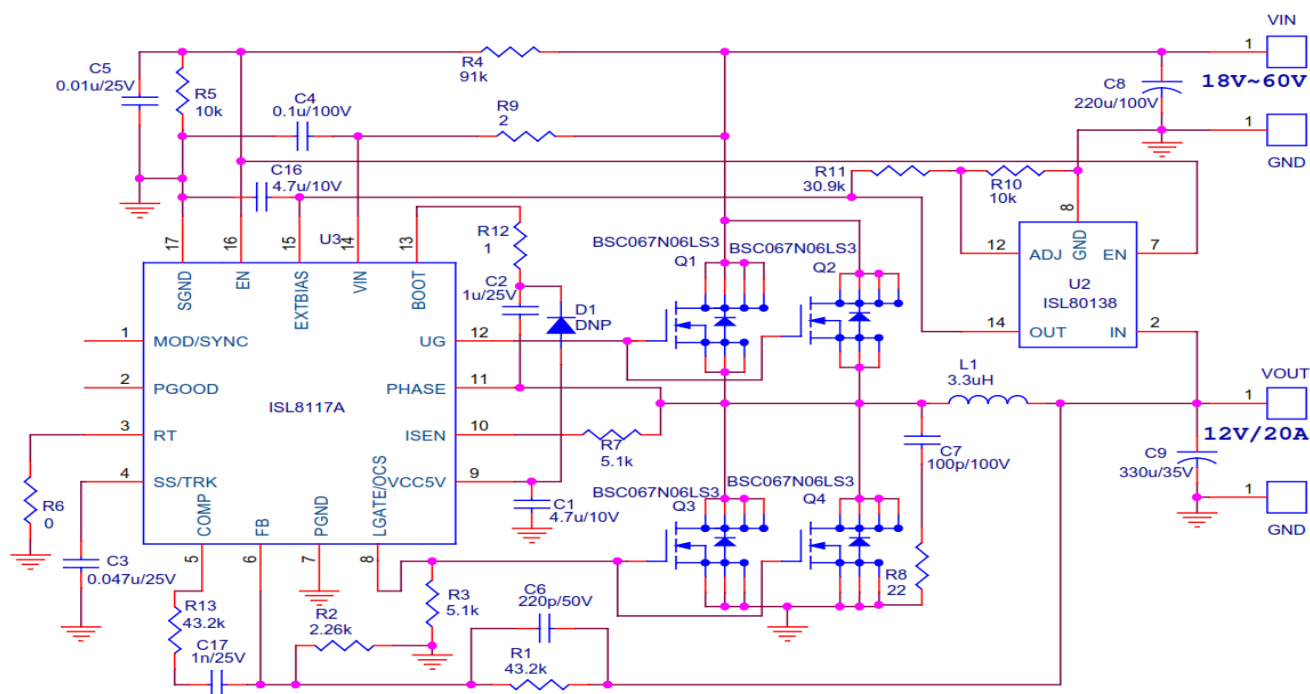


FIGURE 4. ISL8117AEVAL1Z EVALUATION BOARD SCHEMATIC

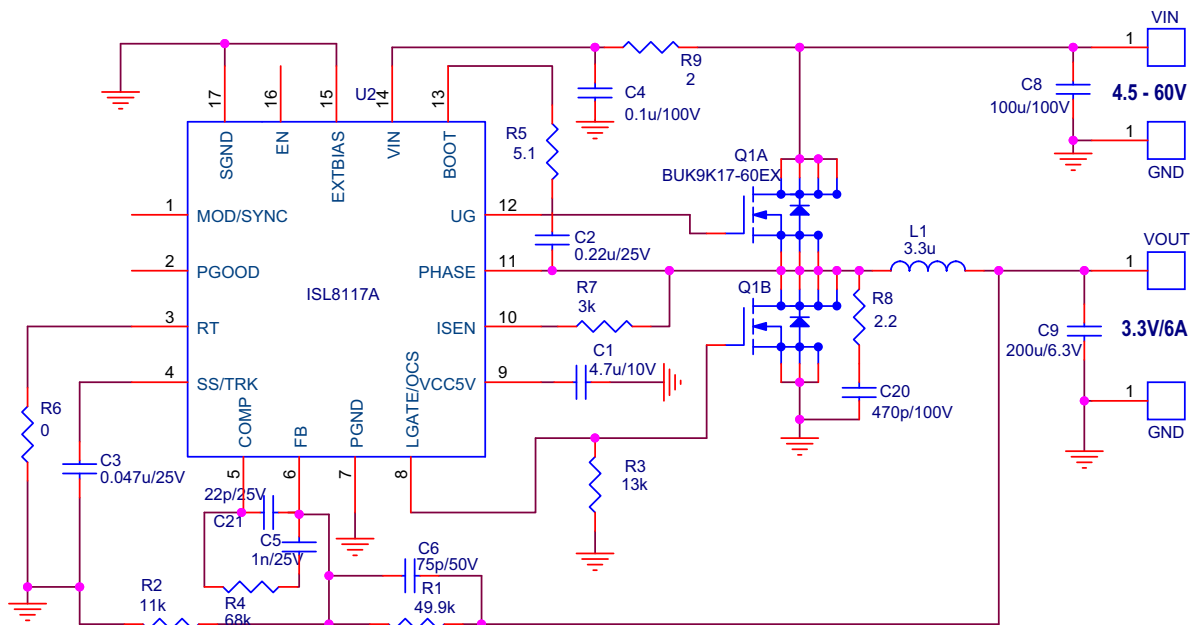


FIGURE 5. ISL8117AEVAL2Z EVALUATION BOARD SCHEMATIC

## Absolute Maximum Ratings

|                                                          |                                  |
|----------------------------------------------------------|----------------------------------|
| VCC5V to GND                                             | -0.3V to +5.9V                   |
| EXTBIAS to GND                                           | -0.3V to +5.9V                   |
| VIN to GND                                               | -0.3V to +62.5V                  |
| BOOT/UGATE to PHASE                                      | -0.3V to VCC5V+0.3V              |
| PHASE and ISEN to GND                                    | -5V (<20ns)/-0.3V (DC) to +62.5V |
| EN, PGOOD, SS/TRK, FB, COMP to GND                       | -0.3V to VCC5V+0.3V              |
| LGATE/OCS to GND                                         | -0.3V to VCC5V+0.3V              |
| RT, MOD/SYNC to GND                                      | -0.3V to VCC5V+0.3V              |
| VCC5V Short-circuit to GND Duration                      | 1s                               |
| ESD Rating                                               |                                  |
| Human Body Model (Tested per JS-001-2010)                | 4kV                              |
| Machine Model (Tested per JESD22-A115C)                  | 300V                             |
| Charge Device Model (Tested per JESD22-C101E)            | 2kV                              |
| Latch-up (Tested per JESD78D; Class II, Level A, +125°C) | 100mA                            |

## Thermal Information

|                                |                           |                      |
|--------------------------------|---------------------------|----------------------|
| Thermal Resistance (Typical)   | $\theta_{JA}$ (°C/W)      | $\theta_{JC}$ (°C/W) |
| 16 Ld QFN Package (Notes 4, 5) | 40                        | 2.5                  |
| Maximum Junction Temperature   | -55°C to +150°C           |                      |
| Maximum Operating Temperature  | -40°C to +125°C           |                      |
| Maximum Storage Temperature    | -65°C to +150°C           |                      |
| Pb-free Reflow Profile         | see <a href="#">TB493</a> |                      |

## Recommended Operating Conditions

|                |                 |
|----------------|-----------------|
| Temperature    | -40°C to +125°C |
| VIN to GND     | 4.5V to 60V     |
| VCC5V to GND   | -0.1V to 5.5V   |
| EXTBIAS to GND | -0.1V to +5.5V  |

CAUTION: Do not operate at or near the maximum ratings listed for extended periods of time. Exposure to such conditions may adversely impact product reliability and result in failures not covered by warranty.

### NOTES:

- $\theta_{JA}$  is measured in free air with the component mounted on a high effective thermal conductivity test board with “direct attach” features. See Tech Brief [TB379](#).
- For  $\theta_{JC}$ , the “case temp” location is the center of the exposed metal pad on the package underside.

**Electrical Specifications** Recommended operating conditions unless otherwise noted. Refer to [“Block Diagram” on page 5](#) and [“Typical Application Schematics” on page 6](#). VIN = 4.5V to 60V, or VCC5V = 5V ±10%, C\_VCC5V = 4.7µF, TA = -40°C to +125°C, Typical values are at TA = +25°C, unless otherwise specified. **Boldface limits apply across the operating temperature range, -40°C to +125°C.**

| SYMBOL                                         | PARAMETER                                    | TEST CONDITIONS             | MIN<br>(Note 9) | TYP  | MAX<br>(Note 9) | UNIT |
|------------------------------------------------|----------------------------------------------|-----------------------------|-----------------|------|-----------------|------|
| <b>VIN SUPPLY</b>                              |                                              |                             |                 |      |                 |      |
| VIN                                            | Input Voltage Range                          |                             | <b>4.5</b>      |      | <b>60</b>       | V    |
| <b>VIN SUPPLY CURRENT</b>                      |                                              |                             |                 |      |                 |      |
| I_VINQ                                         | Shutdown Current ( <a href="#">Note 7</a> )  | EN = 0<br>PGOOD is floating |                 | 5    | <b>10</b>       | µA   |
| I_VINOP                                        | Operating Current ( <a href="#">Note 8</a> ) | PGOOD is floating           |                 | 2.5  | <b>4</b>        | mA   |
| <b>VCC5V SUPPLY (<a href="#">Note 6</a>)</b>   |                                              |                             |                 |      |                 |      |
| VCC                                            | Operation Voltage                            | VIN = 12V, IL = 0mA         | <b>4.85</b>     | 5.1  | <b>5.4</b>      | V    |
|                                                | Internal LDO Output Voltage                  | VIN = 4.5V, IL = 30mA       | <b>4.1</b>      | 4.4  |                 | V    |
|                                                | Internal LDO Output Voltage                  | VIN > 5.6V, IL = 75mA       | <b>4.75</b>     | 5.05 |                 | V    |
| I_VCC_MAX                                      | Maximum Supply Current of Internal LDO       | V_VCC5V = 0V, VIN = 12V     |                 | 120  |                 | mA   |
| <b>EXTBIAS SUPPLY (<a href="#">Note 6</a>)</b> |                                              |                             |                 |      |                 |      |
| V_EXT_THR                                      | Switch Over Threshold Voltage, Rising        | EXTBIAS voltage             | <b>4.5</b>      | 4.7  | <b>4.9</b>      | V    |
| V_EXT_THF                                      | Switch Over Threshold Voltage, Falling       | EXTBIAS voltage             | <b>4.2</b>      | 4.5  | <b>4.65</b>     | V    |
| R_EXT                                          | Internal Switch ON-resistance                | VIN = 12V                   |                 | 1.5  |                 | Ω    |
| <b>UNDERVOLTAGE LOCKOUT</b>                    |                                              |                             |                 |      |                 |      |
| V_UVLOTHR                                      | Undervoltage Lockout, Rising                 | VIN voltage, 0mA on VCC5V   | <b>3.7</b>      | 3.90 | <b>4.2</b>      | V    |
| V_UVLOTHF                                      | Undervoltage Lockout, Falling                | VIN voltage, 0mA on VCC5V   | <b>3.35</b>     | 3.50 | <b>3.85</b>     | V    |
| <b>EN THRESHOLD</b>                            |                                              |                             |                 |      |                 |      |
| V_ENSS_THR                                     | EN Rise Threshold                            | VIN = 12V                   | <b>1.25</b>     | 1.60 | <b>1.95</b>     | V    |
| V_ENSS_THF                                     | EN Fall Threshold                            | VIN = 12V                   | <b>1.05</b>     | 1.25 | <b>1.55</b>     | V    |
| V_ENSS_HYST                                    | EN Hysteresis                                | VIN = 12V                   | <b>180</b>      | 350  | <b>500</b>      | mV   |
| <b>SOFT-START CURRENT</b>                      |                                              |                             |                 |      |                 |      |
| I_SS                                           | SS/TRK Soft-start Charge Current             | SS/TRK = 0V                 |                 | 2.00 |                 | µA   |

# ISL8117A

**Electrical Specifications** Recommended operating conditions unless otherwise noted. Refer to [“Block Diagram” on page 5](#) and [“Typical Application Schematics” on page 6](#).  $V_{IN}$  = 4.5V to 60V, or  $V_{CC5V}$  =  $5V \pm 10\%$ ,  $C_{VCC5V}$  =  $4.7\mu F$ ,  $T_A$  =  $-40^\circ C$  to  $+125^\circ C$ , Typical values are at  $T_A$  =  $+25^\circ C$ , unless otherwise specified. **Boldface limits apply across the operating temperature range,  $-40^\circ C$  to  $+125^\circ C$ .** (Continued)

| SYMBOL                                        | PARAMETER                                            | TEST CONDITIONS                       | MIN<br>(Note 9) | TYP   | MAX<br>(Note 9) | UNIT       |
|-----------------------------------------------|------------------------------------------------------|---------------------------------------|-----------------|-------|-----------------|------------|
| <b>DEFAULT INTERNAL MINIMUM SOFT-STARTING</b> |                                                      |                                       |                 |       |                 |            |
| $t_{SS\_MIN}$                                 | Default Internal Output Ramping Time                 | SS/TRK open                           |                 | 1.5   |                 | ms         |
| <b>POWER-GOOD MONITORS</b>                    |                                                      |                                       |                 |       |                 |            |
| $V_{PGOV}$                                    | PGOOD Upper Threshold                                |                                       | <b>109</b>      | 112.5 | <b>115</b>      | %          |
| $V_{PGUV}$                                    | PGOOD Lower Threshold                                |                                       | <b>85</b>       | 87.5  | <b>92</b>       | %          |
| $V_{PGLow}$                                   | PGOOD Low Level Voltage                              | $I_{SINK} = 2mA$                      |                 |       | <b>0.35</b>     | V          |
| $I_{PGLKG}$                                   | PGOOD Leakage Current                                | PGOOD = 5V                            |                 | 20    | <b>150</b>      | nA         |
| <b>PGOOD TIMING</b>                           |                                                      |                                       |                 |       |                 |            |
| $t_{PGR}$                                     | $V_{OUT}$ Rising Threshold to PGOOD Rising (Note 11) |                                       |                 | 1.1   | <b>5</b>        | ms         |
| $t_{PGF}$                                     | $V_{OUT}$ Falling Threshold to PGOOD Falling         |                                       |                 | 75    |                 | $\mu s$    |
| <b>REFERENCE SECTION</b>                      |                                                      |                                       |                 |       |                 |            |
| $V_{REF}$                                     | Internal Reference Voltage                           |                                       |                 | 0.600 |                 | V          |
|                                               | Reference Voltage Accuracy                           | $T_A = 0^\circ C$ to $+85^\circ C$    | -0.75           |       | +0.75           | %          |
|                                               |                                                      | $T_A = -40^\circ C$ to $+125^\circ C$ | -1.00           |       | +1.00           | %          |
| $I_{FBLKG}$                                   | FB Bias Current                                      |                                       | <b>-40</b>      | 0     | <b>40</b>       | nA         |
| <b>PWM CONTROLLER ERROR AMPLIFIERS</b>        |                                                      |                                       |                 |       |                 |            |
|                                               | Input Common-mode Range                              | $V_{IN} = 12V$                        | 0               |       | $V_{CC5V} - 2$  | V          |
|                                               | DC Gain                                              | $V_{IN} = 12V$                        |                 | 88    |                 | dB         |
| GBW                                           | Gain-BW Product                                      | $V_{IN} = 12V$                        |                 | 8     |                 | MHz        |
| SR                                            | Slew Rate                                            | $V_{IN} = 12V$                        |                 | 2.0   |                 | V/ $\mu s$ |
|                                               | COMP $V_{OL}$                                        | $V_{IN} = 12V$                        |                 | 0.4   |                 | V          |
|                                               | COMP $V_{OH}$                                        | $V_{IN} = 12V$                        |                 | 2.6   |                 | V          |
|                                               | COMP Sink Current (Note 12)                          | $V_{COMP} = 2.5V$                     |                 |       | 30              | mA         |
|                                               | COMP Source Current (Note 12)                        | $V_{COMP} = 2.5V$                     |                 |       | 30              | mA         |
| <b>PWM REGULATOR</b>                          |                                                      |                                       |                 |       |                 |            |
| $t_{OFF\_MIN}$                                | Minimum Off Time                                     |                                       |                 | 308   |                 | ns         |
| $t_{ON\_MIN}$                                 | Minimum On Time                                      |                                       |                 | 40    |                 | ns         |
| $DV_{RAMP}$                                   | Peak-to-peak Sawtooth Amplitude                      | $V_{IN} = 20V$                        |                 | 1.0   |                 | V          |
|                                               |                                                      | $V_{IN} = 12V$                        |                 | 0.6   |                 | V          |
|                                               | Ramp Offset                                          |                                       |                 | 1.0   |                 | V          |
| <b>SWITCHING FREQUENCY</b>                    |                                                      |                                       |                 |       |                 |            |
| $f_{SW}$                                      | Switching Frequency                                  | $R_T = 36k$                           | <b>890</b>      | 1050  | <b>1195</b>     | kHz        |
|                                               | Switching Frequency                                  | $R_T = 16.5k$                         | <b>1650</b>     | 2000  | <b>2375</b>     | kHz        |
|                                               | Switching Frequency                                  | RT PIN connect to GND                 | <b>250</b>      | 300   | <b>350</b>      | kHz        |
|                                               | Switching Frequency                                  | RT PIN connect to $V_{CC5V}$ or FLOAT | <b>515</b>      | 600   | <b>645</b>      | kHz        |
| $V_{RT}$                                      | RT Voltage                                           | $R_T = 36k$                           |                 | 770   |                 | mV         |
| <b>SYNCHRONIZATION</b>                        |                                                      |                                       |                 |       |                 |            |
| $F_{SYNC}$                                    | SYNC Synchronization Range                           | $R_T = 36k\Omega$                     | <b>1230</b>     |       | <b>2200</b>     | kHz        |

# ISL8117A

**Electrical Specifications** Recommended operating conditions unless otherwise noted. Refer to [“Block Diagram” on page 5](#) and [“Typical Application Schematics” on page 6](#).  $V_{IN}$  = 4.5V to 60V, or  $V_{CC5V}$  = 5V  $\pm 10\%$ ,  $C_{VCC5V}$  = 4.7 $\mu$ F,  $T_A$  = -40°C to +125°C, Typical values are at  $T_A$  = +25°C, unless otherwise specified. **Boldface limits apply across the operating temperature range, -40°C to +125°C. (Continued)**

| SYMBOL                                | PARAMETER                                 | TEST CONDITIONS    | MIN<br>(Note 9) | TYP  | MAX<br>(Note 9) | UNIT     |
|---------------------------------------|-------------------------------------------|--------------------|-----------------|------|-----------------|----------|
| <b>DIODE EMULATION MODE DETECTION</b> |                                           |                    |                 |      |                 |          |
| $V_{MODETHH}$                         | MOD/SYNC Threshold High (Note 12)         |                    | <b>1.1</b>      | 1.6  | <b>2.1</b>      | V        |
| $V_{MODEHYS}$                         | MOD/SYNC Hysteresis (Note 12)             |                    |                 | 200  |                 | mV       |
| $V_{CROSS}$                           | Diode Emulation Phase Threshold (Note 10) | $V_{IN} = 12V$     |                 | -3   |                 | mV       |
| <b>PWM GATE DRIVER</b>                |                                           |                    |                 |      |                 |          |
| $I_{UGSRC}$                           | Upper Drive Source Current                |                    |                 | 2000 |                 | mA       |
| $I_{UGSNK}$                           | Upper Drive Sink Current                  |                    |                 | 2000 |                 | mA       |
| $I_{LGSRC}$                           | Lower Drive Source Current                |                    |                 | 2000 |                 | mA       |
| $I_{LGSNK}$                           | Lower Drive Sink Current                  |                    |                 | 4000 |                 | mA       |
| $R_{UG\_UP}$                          | Upper Drive Pull-up                       | $V_{CC5V} = 5V$    |                 | 1.5  |                 | $\Omega$ |
| $R_{UG\_DN}$                          | Upper Drive Pull-down                     | $V_{CC5V} = 5V$    |                 | 1.5  |                 | $\Omega$ |
| $R_{LG\_UP}$                          | Lower Drive Pull-up                       | $V_{CC5V} = 5V$    |                 | 1.0  |                 | $\Omega$ |
| $R_{LG\_DN}$                          | Lower Drive Pull-down                     | $V_{CC5V} = 5V$    |                 | 0.8  |                 | $\Omega$ |
| $t_{GR\_UP}$                          | Upper Drive Rise Time                     | $C_{OUT} = 1000pF$ |                 | 9.0  |                 | ns       |
| $t_{GF\_UP}$                          | Upper Drive Fall Time                     | $C_{OUT} = 1000pF$ |                 | 8.0  |                 | ns       |
| $t_{GR\_DN}$                          | Lower Drive Rise Time                     | $C_{OUT} = 1000pF$ |                 | 7.0  |                 | ns       |
| $t_{GF\_DN}$                          | Lower Drive Fall Time                     | $C_{OUT} = 1000pF$ |                 | 6.1  |                 | ns       |
| <b>OVERVOLTAGE PROTECTION</b>         |                                           |                    |                 |      |                 |          |
| $V_{OVTH}$                            | OVP Threshold                             |                    | <b>116</b>      | 121  | <b>127</b>      | %        |
| <b>OVERCURRENT PROTECTION</b>         |                                           |                    |                 |      |                 |          |
| $I_{OCSET-CS}$                        | OC Set Current Source                     | $LGATE/OCS = 0V$   | <b>9</b>        | 10.5 | <b>11.5</b>     | $\mu A$  |
| <b>OVER-TEMPERATURE</b>               |                                           |                    |                 |      |                 |          |
| $T_{OT-TH}$                           | Over-temperature Shutdown                 |                    |                 | 160  |                 | °C       |
| $T_{OT-HYS}$                          | Over-temperature Hysteresis               |                    |                 | 15   |                 | °C       |

## NOTES:

- In normal operation, where the device is supplied with voltage on the  $V_{IN}$  pin, the  $V_{CC5V}$  pin provides a 5V output capable of 75mA (minimum). When the device is supplied by an external 5V supply on the  $EXTBIAS$  pin, the internal LDO regulator is disabled. The voltage at  $V_{CC5V}$  should not exceed the voltage at  $V_{IN}$  at any time. (Refer to [“Pin Descriptions” on page 3](#) for more details.)
- This is the total shutdown current with  $V_{IN} = 5.6V$  and 60V.
- Operating current is the supply current consumed when the device is active but not switching. It does not include gate drive current.
- Parameters with MIN and/or MAX limits are 100% tested at +25°C, unless otherwise specified. Temperature limits established by characterization and are not production tested.
- Threshold voltage at PHASE pin for turning off the bottom MOSFET during DEM.
- When soft-start time is less than 4.5ms,  $t_{PGR}$  increases. With internal soft-start (the fastest soft-start time),  $t_{PGR}$  increases close to its max limit 5ms.
- Compliance to limits is assured by characterization and design.

## Typical Performance Curves

Oscilloscope plots are taken using the ISL8117AEVAL1Z evaluation board,  $V_{IN} = 18V$  to 60V,  $V_{OUT} = 12V$ ,  $I_{OUT} = 20A$  unless otherwise noted.

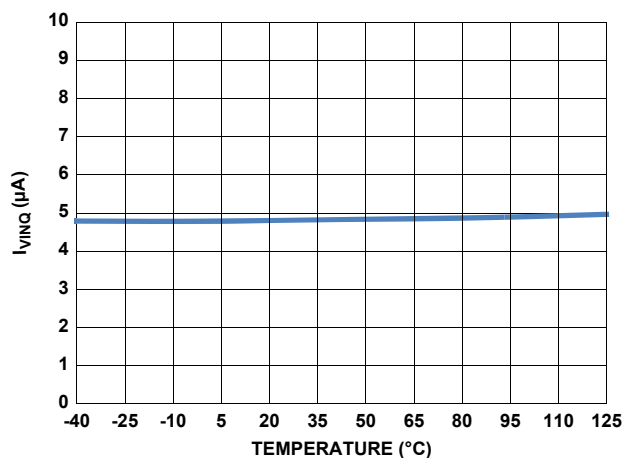


FIGURE 6. SHUTDOWN CURRENT vs TEMPERATURE

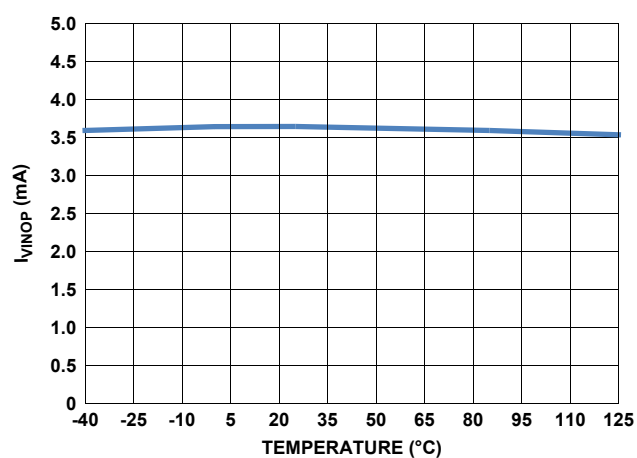


FIGURE 7. QUIESCENT CURRENT vs TEMPERATURE

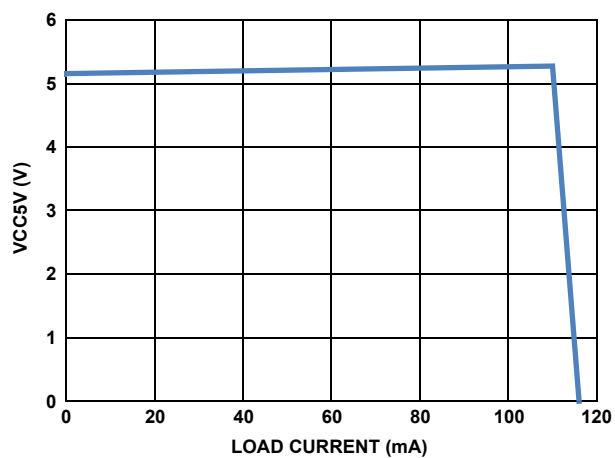


FIGURE 8. VCC5V LOAD REGULATION

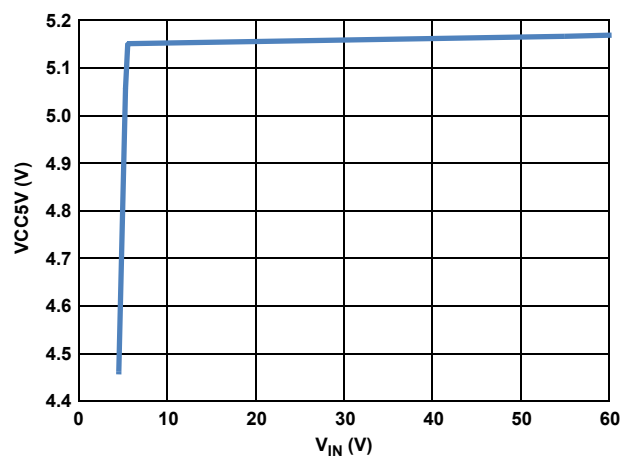


FIGURE 9. VCC5V LINE REGULATION

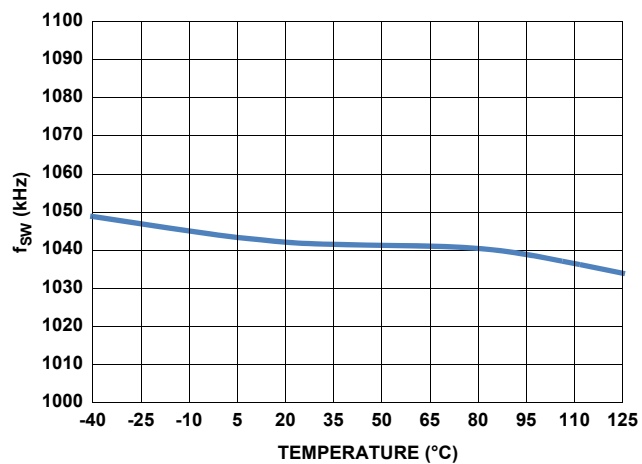


FIGURE 10. SWITCHING FREQUENCY vs TEMPERATURE ( $R_T = 36k\Omega$ )

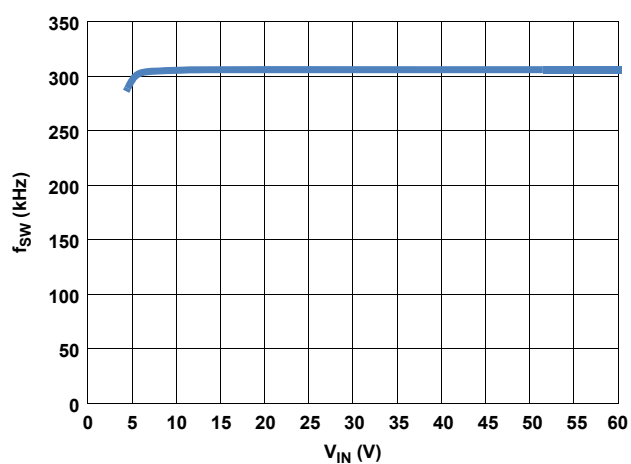


FIGURE 11. SWITCHING FREQUENCY vs  $V_{IN}$

## Typical Performance Curves

Oscilloscope plots are taken using the ISL8117AEVAL1Z evaluation board,  $V_{IN} = 18V$  to 60V,  $V_{OUT} = 12V$ ,  $I_{OUT} = 20A$  unless otherwise noted. (Continued)

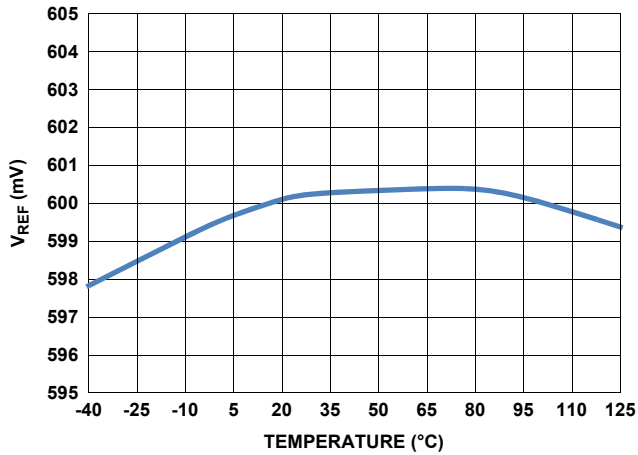


FIGURE 12. REFERENCE VOLTAGE vs TEMPERATURE

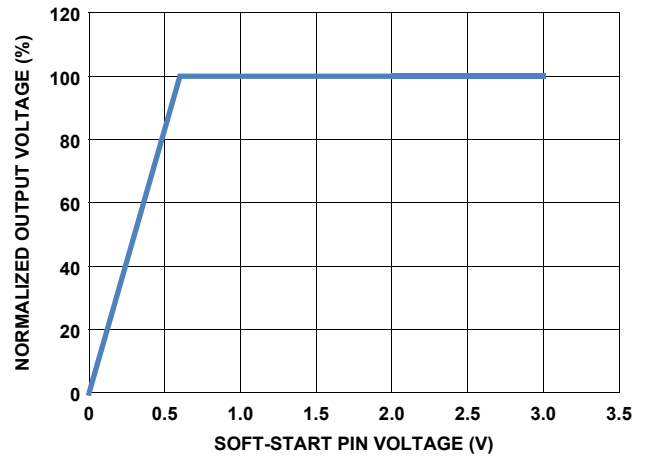


FIGURE 13. NORMALIZED OUTPUT VOLTAGE vs VOLTAGE ON SOFT-START PIN

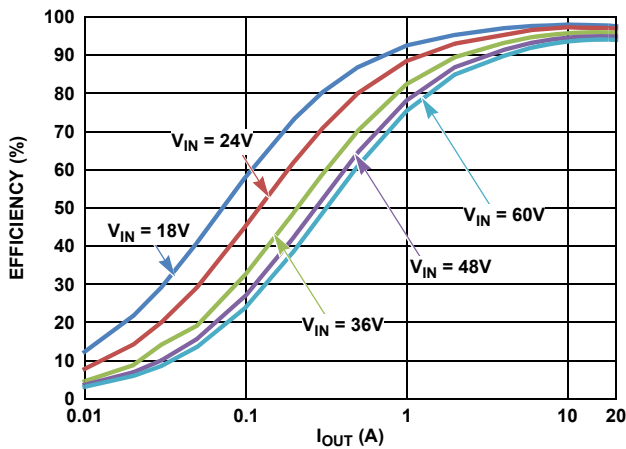


FIGURE 14. CCM MODE EFFICIENCY

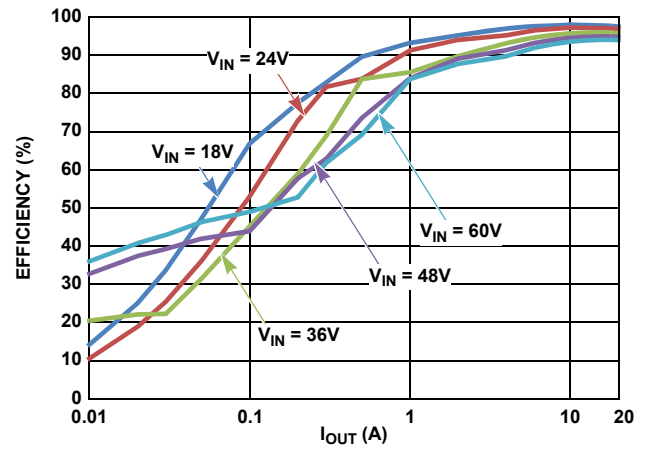


FIGURE 15. DEM MODE EFFICIENCY

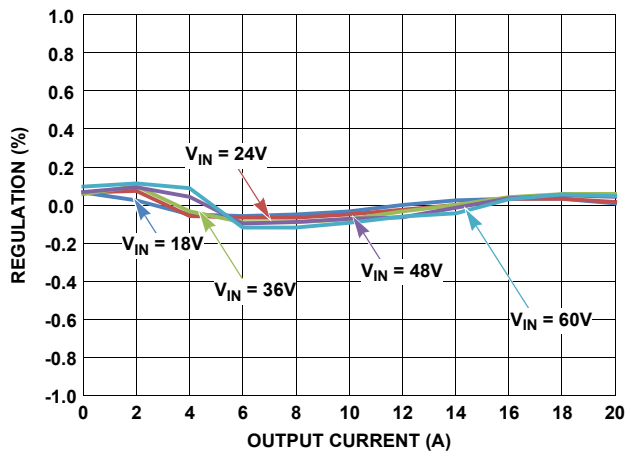


FIGURE 16. CCM MODE LOAD REGULATION

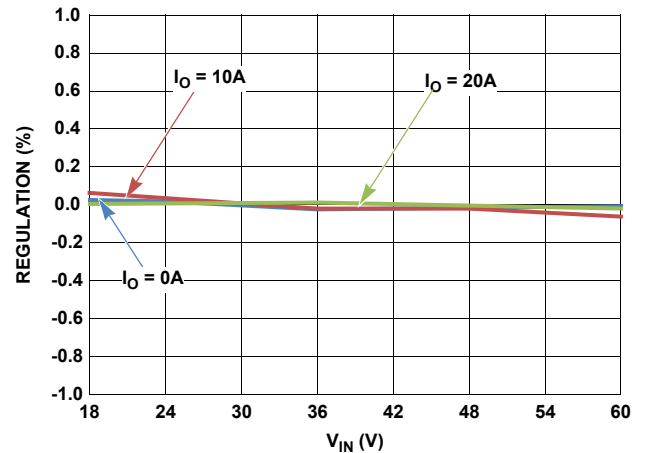


FIGURE 17. CCM MODE LINE REGULATION

## Typical Performance Curves

Oscilloscope plots are taken using the ISL8117AEVAL1Z evaluation board,  $V_{IN} = 18V$  to 60V,  $V_{OUT} = 12V$ ,  $I_{OUT} = 20A$  unless otherwise noted. (Continued)

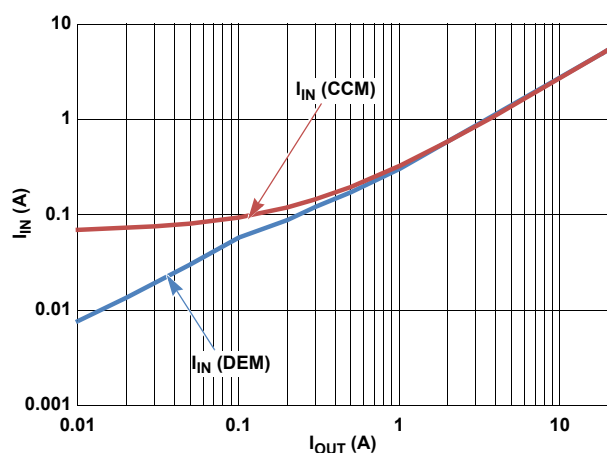


FIGURE 18. INPUT CURRENT COMPARISON WITH MODE = CCM/DEM,  $V_{IN} = 48V$

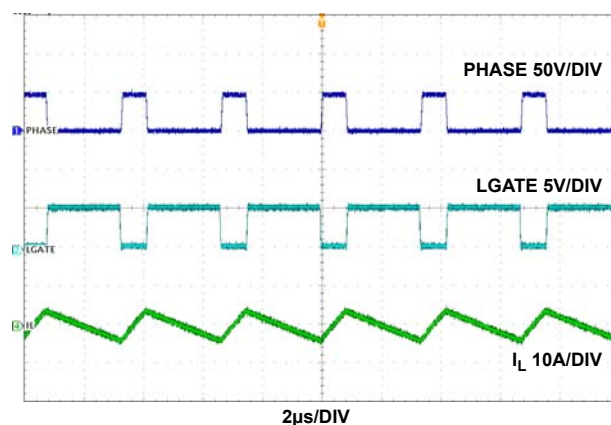


FIGURE 19. PHASE, LGATE, AND INDUCTOR CURRENT WAVEFORMS

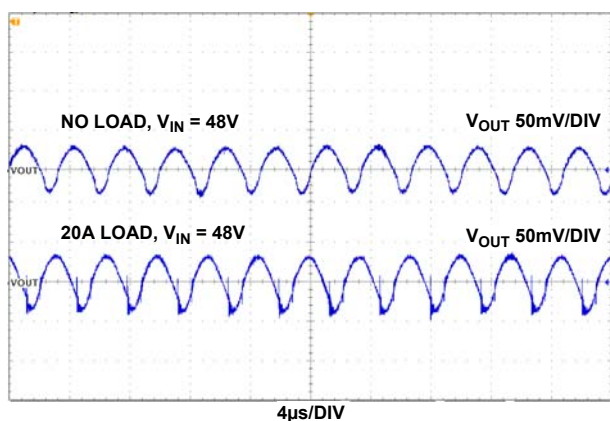


FIGURE 20. OUTPUT RIPPLE, MODE = CCM

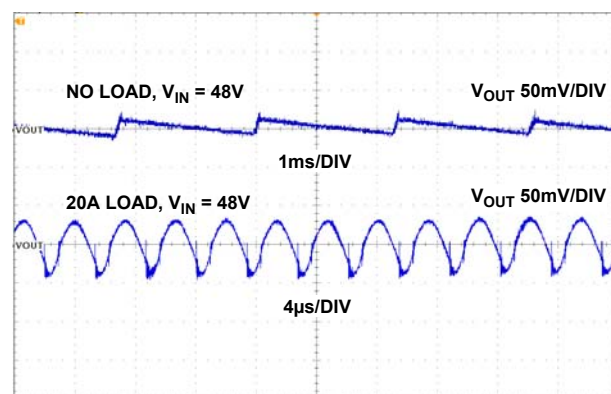


FIGURE 21. OUTPUT RIPPLE, MODE = DEM

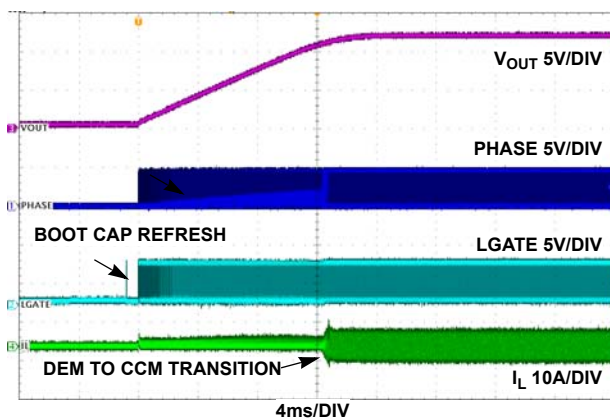


FIGURE 22. START-UP WAVEFORMS; MODE = CCM, LOAD = 0A,  $V_{IN} = 48V$

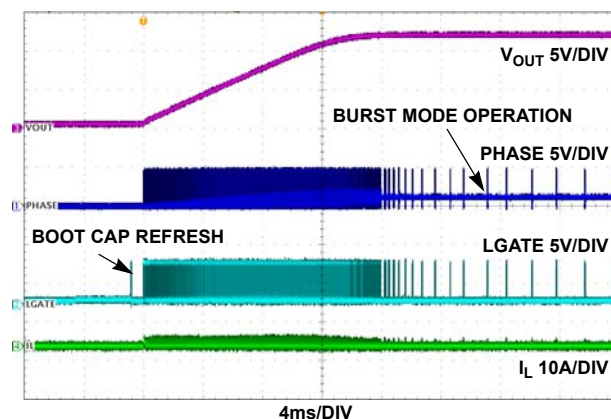


FIGURE 23. START-UP WAVEFORMS; MODE = DEM, LOAD = 0A,  $V_{IN} = 48V$

## Typical Performance Curves

Oscilloscope plots are taken using the ISL8117AEVAL1Z evaluation board,  $V_{IN} = 18V$  to 60V,  $V_{OUT} = 12V$ ,  $I_{OUT} = 20A$  unless otherwise noted. (Continued)

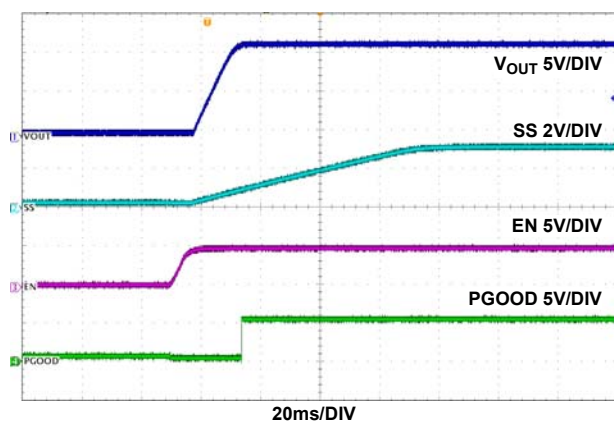


FIGURE 24. START-UP WAVEFORMS; MODE = CCM, LOAD = 0A,  $V_{IN} = 48V$

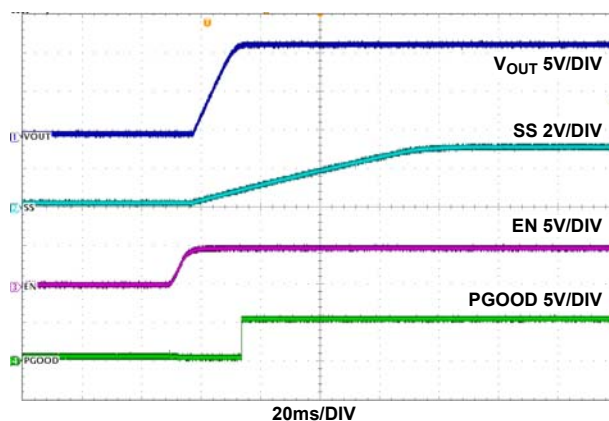


FIGURE 25. START-UP WAVEFORMS; MODE = DEM, LOAD = 0A,  $V_{IN} = 48V$

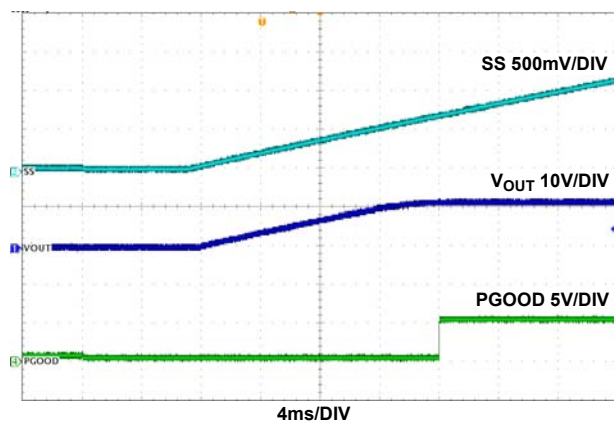


FIGURE 26. TRACKING;  $V_{IN} = 48V$ , LOAD = 0A, MODE = CCM

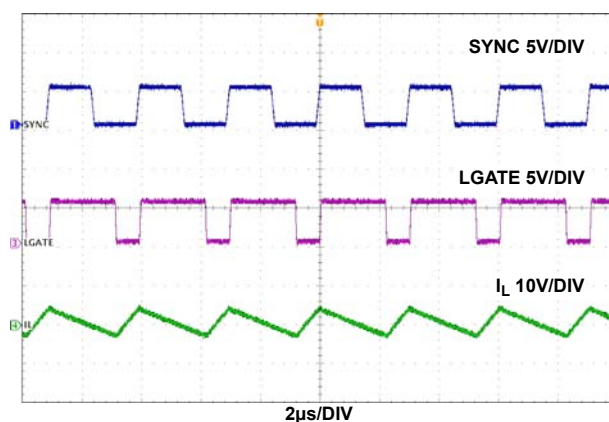


FIGURE 27. FREQUENCY SYNCHRONIZATION;  $V_{IN} = 48V$ , LOAD = 0A, DEFAULT  $f_{SW} = 300kHz$ , SYNC  $f_{SW} = 330kHz$

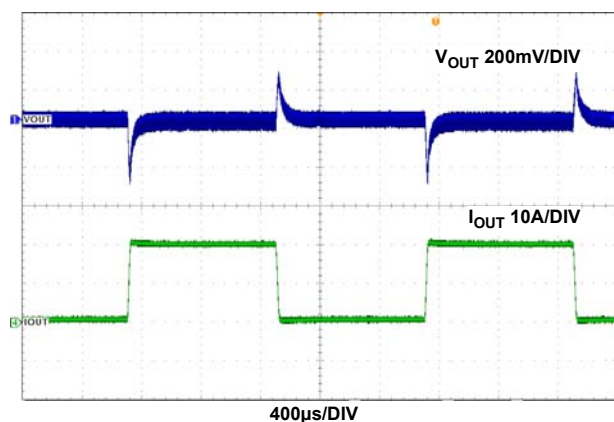


FIGURE 28. LOAD TRANSIENT RESPONSE;  $V_{IN} = 48V$ , 0A TO 20A 1A/μs STEP LOAD, CCM MODE

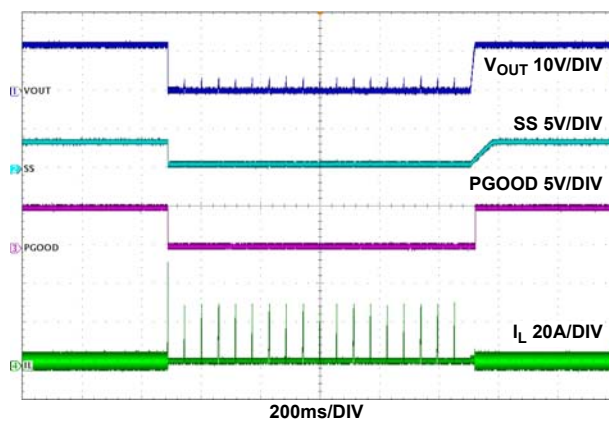


FIGURE 29. OCP RESPONSE, OUTPUT SHORT-CIRCUITED FROM NO LOAD TO GROUND AND RELEASED, CCM MODE,  $V_{IN} = 48V$

## Functional Description

### General Description

The ISL8117A integrates control circuits for a synchronous buck converter. The driver and protection circuits are also integrated to simplify the end design.

The part has an independent enable/disable control line EN, which provides a flexible power-up sequencing and a simple VIN UVP implementation. The soft-start time is programmable by adjusting the soft-start capacitor connected from SS/TRK.

The valley current mode control scheme with input voltage feed-forward ramp simplifies loop compensation and provides excellent rejection to input voltage variation.

### Input Voltage Range

The ISL8117A is designed to operate from input supplies ranging from 4.5V to 60V.

The input voltage range can be effectively limited by the available minimum PWM off-time as shown in [Equation 2](#).

$$V_{IN(min)} \geq \left( \frac{V_{OUT} + V_{d1}}{1 - t_{OFF(min)} \times \text{Frequency}} \right) + V_{d2} - V_{d1} \quad (\text{EQ. 2})$$

Where,

$V_{d1}$  = sum of the parasitic voltage drops in the inductor discharge path, including the lower FET, inductor and PC board.  $V_{d2}$  = sum of the voltage drops in the charging path, including the upper FET, inductor and PC board resistances.

$t_{OFF(min)} = 308\text{ns}$ .

The maximum input voltage and minimum output voltage is limited by the minimum on-time ( $t_{ON(min)}$ ) as shown in [Equation 3](#).

$$V_{IN(max)} \leq \left( \frac{V_{OUT}}{t_{ON(min)} \times \text{Frequency}} \right) \quad (\text{EQ. 3})$$

Where,  $t_{ON(min)} = 40\text{ns}$  in CCM and  $60\text{ns}$  in DEM.

### Internal 5V Linear Regulator (VCC5V) and External VCC Bias Supply (EXTBIAS)

All the ISL8117A functions can be internally powered from an on-chip, low dropout 5V regulator or an external 5V bias voltage via the EXTBIAS pin. Bypass the linear regulator's output (VCC5V) with a  $4.7\mu\text{F}$  capacitor to the power ground. The ISL8117A also employs an undervoltage lockout circuit, which disables all regulators when VCC5V falls below 3.5V.

The internal LDO can source over 75mA to supply the IC, power the low-side gate driver and charge the boot capacitor. When driving large FETs at high switching frequency, little or no regulator current may be available for external loads.

For example, a single large FET with  $15\text{nC}$  total gate charge requires  $15\text{nC} \times 300\text{kHz} = 4.5\text{mA}$  ( $15\text{nC} \times 600\text{kHz} = 9\text{mA}$ ). Also, at higher input voltages with larger FETs, the power dissipation across the internal 5V will increase. Excessive dissipation across this regulator must be avoided to prevent junction temperature

rise. Thermal protection may be triggered if die temperature increases above  $+160^\circ\text{C}$  due to excessive power dissipation.

When large MOSFETs are used, an external 5V bias voltage can be applied to the EXTBIAS pin to alleviate excessive power dissipation. Voltage at the EXTBIAS pin must always be lower than the voltage at the VIN pin to prevent biasing of the power stage through EXTBIAS and VCC5V. An external UVLO circuit might be necessary to guarantee smooth soft-starting.

The internal LDO has an overcurrent limit of typically 120mA. For better efficiency, connect VCC5V to VIN for  $5\text{V} \pm 10\%$  input applications.

### Enable and Soft-Start Operation

Pulling the EN pin high or low can enable or disable the controller. When the EN pin voltage is higher than 1.6V, the controller is enabled to initialize its internal circuit. After the VCC5V pin reaches the UVLO threshold, ISL8117A soft-start circuitry becomes active. The internal  $2\mu\text{A}$  charge current begins charging up the soft-start capacitor connected from the SS/TRK pin to GND. The voltage error amplifier reference voltage is clamped to the voltage on the SS/TRK pin. The output voltage thus rises from 0V to regulation as SS/TRK rises from 0V to 0.6V. Charging of the soft-start capacitor continues until the voltage on the SS/TRK pin reaches 3V.

Typical applications for ISL8117A use programmable analog soft-start or SS/TRK pin for tracking. The soft-start time can be set by the value of the soft-start capacitor connected from the SS/TRK to GND. Inrush current during start-up can be alleviated by adjusting the soft-starting time.

The typical soft-start time is set according to [Equation 4](#):

$$t_{SS} = 0.6V \left( \frac{C_{SS}}{2\mu\text{A}} \right) \quad (\text{EQ. 4})$$

When the soft-starting time set by external  $C_{SS}$  or tracking is less than 1.5ms, an internal soft-start circuit of 1.5ms takes over the soft-start.

PGOOD will toggle to high when the corresponding output is up and in regulation.

Pulling the EN low disables the PWM output and internal LDO to achieve low standby current. The SS/TRK pin will also be discharged to GND by an internal MOSFET with  $70\Omega$   $r_{DS(ON)}$ .

### Output Voltage Programming

The ISL8117A provides a precision 0.6V internal reference voltage to set the output voltage. Based on this internal reference, the output voltage can thus be set from 0.6V up to a level determined by the input voltage, the maximum duty cycle and the conversion efficiency of the circuit.

A resistive divider from the output to ground sets the output voltage. The center point of the divider shall be connected to the FB pin. The output voltage value is determined by [Equation 5](#).

$$V_{OUT} = 0.6V \left( \frac{R_1 + R_2}{R_2} \right) \quad (\text{EQ. 5})$$

Where  $R_1$  is the top resistor of the feedback divider network and  $R_2$  is the bottom resistor connected from FB to ground.

## Tracking Operation

The ISL8117A can be set up to track an external supply. To implement tracking, a resistive divider is connected between the external supply output and ground. The center point of the divider shall be connected to the SS/TRK pin of ISL8117A. The resistive divider ratio sets the ramping ratio between the two voltage rails. To implement coincident tracking, set the tracking resistive divider ratio exactly the same as the ISL8117A output resistive divider given by [Equation 5 on page 14](#). Make sure that the voltage at SS/TRK is greater than 0.6V when the master rail reaches regulation.

To minimize the impact of the 2μA soft-start current on the tracking function, it is recommended to use resistors of less than 10kΩ for the tracking resistive divider.

When Overcurrent Protection (OCP) is triggered, the internal minimum soft-start circuit determines the OCP soft-start hiccup.

## Light-Load Efficiency Enhancement

When MOD/SYNC is tied to VCC5V, the ISL8117A operates in high efficiency diode emulation mode and pulse skipping mode in light-load condition. The inductor current is not allowed to reverse (discontinuous operation). At very light loads, the converter goes into diode emulation and triggers the pulse skipping function. In pulse skipping mode, the upper MOSFET remains off until the output voltage drops to the point the error amplifier output goes above the pulse skipping mode threshold. The minimum  $t_{ON}$  in the pulse skipping mode is 60ns.

## Prebiased Power-Up

The ISL8117A has the ability to soft-start with a prebiased output. The output voltage would not be yanked down during prebiased start-up. The PWM is not active until the soft-start ramp reaches the output voltage times the resistive divider ratio.

Overvoltage protection is alive during soft-starting.

## Frequency Selection

Switching frequency selection is a trade-off between efficiency and component size. Low switching frequency improves efficiency by reducing MOSFET switching loss. To meet the output ripple and load transient requirements, operation at a low switching frequency would require larger inductance and output capacitance. The switching frequency of the ISL8117A is set by a resistor connected from the RT pin to GND according to [Equation 1 on page 4](#).

The frequency setting curve shown in [Figure 30](#) assists in selecting the correct value for  $R_T$ .

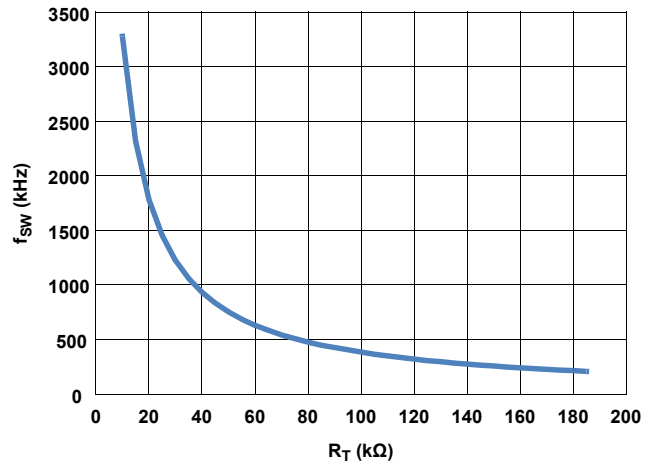


FIGURE 30.  $R_T$  vs SWITCHING FREQUENCY  $f_{SW}$

## Frequency Synchronization

The MOD/SYNC pin may be used to synchronize ISL8117A to an external clock. When the MOD/SYNC pin is connected to an external clock, ISL8117A will synchronize to this external clock frequency. For proper operation, the frequency set by resistor  $R_T$  should be lower than the external clock frequency.

When frequency synchronization is in action, the controllers will enter forced continuous current mode at light load.

## Gate Control Logic

The gate control logic translates the PWM signal into gate drive signals providing amplification, level shifting and shoot-through protection. The gate driver has circuitry that helps optimize the IC performance over a wide range of operational conditions. As MOSFET switching times can vary dramatically from type to type and with input voltage, the gate control logic provides adaptive dead time by monitoring real gate waveforms of both the upper and the lower MOSFETs. Shoot-through control logic provides a 16ns dead time to ensure that both the upper and lower MOSFETs will not turn on simultaneously causing a shoot-through condition.

## Gate Driver

The low-side gate driver is supplied from VCC5V and provide a 4A peak sink current and a 2A peak source current. The high-side gate driver is capable of delivering a 2A peak sink and source current. Gate-drive voltage for the upper N-Channel MOSFET is generated by a flying capacitor boot circuit. A boot capacitor connected from the BOOT pin to the PHASE node provides power to the high-side MOSFET driver. To limit the peak current in the IC, an external resistor may be placed between the BOOT pin and the boot capacitor. This small series resistor also damps any oscillations caused by the resonant tank of the parasitic inductances in the traces of the board and the FET's input capacitance.

At start-up, the low-side MOSFET turns on first and forces PHASE to ground in order to charge the BOOT capacitor to 5V. After the low-side MOSFET turns off, the high-side MOSFET is turned on by closing an internal switch between BOOT and UGATE. This

provides the necessary gate-to-source voltage to turn on the upper MOSFET, an action that boosts the 5V gate drive signal above  $V_{IN}$ . The current required to drive the upper MOSFET is drawn from the internal 5V regulator.

For optimal EMI performance or reducing phase node ringing, a small resistor might be placed between the BOOT pin to the positive terminal of the bootstrap capacitor.

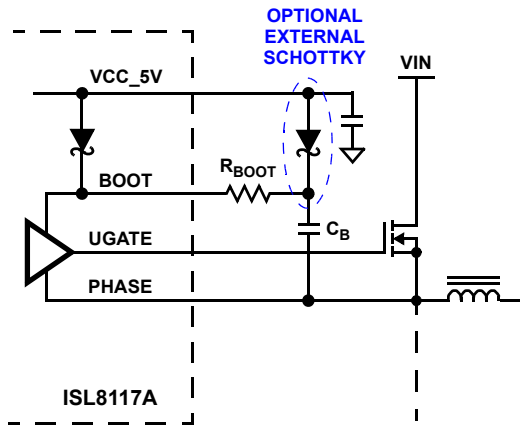


FIGURE 31. UPPER GATE DRIVER CIRCUIT

## Adaptive Dead Time

The ISL8117A incorporates an adaptive dead time algorithm on the synchronous buck PWM controller that optimizes operation with varying MOSFET conditions. This algorithm provides approximately 16ns dead time between the switching of the upper and lower MOSFETs. This dead time is adaptive and allows operation with different MOSFETs without having to externally adjust the dead time using a resistor or capacitor. During turn-off of the lower MOSFET, the LGATE voltage is monitored until it reaches a threshold of 1V, at which time the UGATE is released to rise. Adaptive dead time circuitry monitors the upper MOSFET gate voltage during UGATE turn-off. Once the upper MOSFET gate-to-source voltage has dropped below a threshold of 1V, the LGATE is allowed to rise. It is recommended to not use a resistor between UGATE and LGATE and the respective MOSFET gates as it may interfere with the dead time circuitry.

## Internal Bootstrap Diode

The ISL8117A has an integrated bootstrap diode to help reduce total cost and reduce layout complexity. Simply adding an external capacitor across the BOOT and PHASE pins completes the bootstrap circuit. The bootstrap capacitor can be chosen from [Equation 6](#).

$$C_{BOOT} \geq \frac{Q_{GATE}}{\Delta V_{BOOT}} \quad (EQ. 6)$$

Where  $Q_{GATE}$  is the amount of gate charge required to fully charge the gate of the upper MOSFET. The  $\Delta V_{BOOT}$  term is defined as the allowable droop in the rail of the upper drive.

As an example, suppose an upper MOSFET has a gate charge ( $Q_{GATE}$ ) of 25nC at 5V and also assume the droop in the drive voltage over a PWM cycle is 200mV. Based on the calculation, a bootstrap capacitance of at least 0.125μF is required. The next

larger standard value capacitance of 0.22μF should be used. A good quality ceramic capacitor is recommended.

The internal bootstrap Schottky diode has a resistance of 1.5Ω (typ) at 800mA. Combined with the resistance  $R_{BOOT}$ , this could lead to the boot capacitor charging insufficiently in cases where the bottom MOSFET is turned on for a very short period of time. If such circumstances are expected, an additional external Schottky diode may be added from VCC5V to the positive of the boot capacitor.  $R_{BOOT}$  may still be necessary to lower EMI due to fast turn-on of the upper MOSFET.

## Power-Good Indicator

The power-good pin can be used to monitor the status of the output voltage. PGOOD will be true (open drain) 1.1ms after the FB pin is within ±12.5% of the reference voltage.

There is no extra delay when the PGOOD pin is pulled LOW.

## Protection Circuits

The converter output is monitored and protected against overload, light load and undervoltage conditions.

### Undervoltage Lockout

The ISL8117A includes UVLO protection, which keeps the device in a reset condition until a proper operating voltage is applied. It also shuts down the ISL8117A if the operating voltage drops below a predefined value. The controller is disabled when UVLO is asserted. When UVLO is asserted, PGOOD is valid and will be deasserted.

### Overcurrent Protection

The controller uses the lower MOSFET's ON-resistance,  $r_{DS(ON)}$ , to monitor the current in the converter. The sensed voltage drop is compared with a threshold set by a resistor  $R_{OCSET}$  connected from the LGATE/OCS pin to ground during the initiation stage before soft-start. During the initiation stage, a 10.5μA current source from the LGATE/OCS pin creates a voltage drop on  $R_{OCSET}$ . The voltage drop is then read and stored as the OCP comparator reference.  $R_{OCSET}$  can be calculated by [Equation 7](#).

$$R_{OCSET} = \frac{(r_{DS(ON)})(I_{OC})}{0.7 + 3.5R_{CS}} (k\Omega) \quad (EQ. 7)$$

Where  $I_{OC}$  is the desired overcurrent protection threshold and  $R_{CS}$  is the value of the current sense resistor connected to the ISEN pin. The unit for  $r_{DS(ON)}$  is in mΩ and for  $R_{CS}$  is in kΩ.

If an overcurrent is detected, the upper MOSFET remains off and the lower MOSFET remains on until the next cycle. As a result, the converter will skip a pulse. When the overload condition is removed, the converter will resume normal operation.

If an overcurrent is detected for 2 consecutive clock cycles, the IC enters in a hiccup mode by turning off the gate driver and entering soft-start. The IC will stay off for 50ms before trying to restart. The IC will continue to cycle through soft-start until the overcurrent condition is removed. Hiccup mode is active during soft-start, so care must be taken to ensure that the peak inductor current does not exceed the overcurrent threshold during soft-start.

Because of the nature of this current sensing technique, and to accommodate a wide range of  $r_{DS(ON)}$  variations, the value of the overcurrent threshold should represent an overload current about 150% to 180% of the maximum operating current. If more accurate current protection is desired, place a current sense resistor in series with the lower MOSFET source.

When OCP is triggered, the SS/TRK pin is pulled to ground by an internal MOSFET for hiccup restart. When configured to track another voltage rail, the SS/TRK pin rises up much faster than the internal minimum soft-start ramp. The voltage reference will then be clamped to the internal minimum soft-start ramp. Thus, smooth soft-start hiccup is achieved even with tracking function.

For applications with large inductor ripple current, it is recommended to use a larger  $R_{CS}$  to reduce the current ripple into the ISEN pin to less than  $26\mu A$ , which is the OCP comparator hysteresis. Otherwise, when the load current approaches to the OCP trip point, the OCP comparator can trip and reset in one switching cycle. The overcurrent condition cannot last for 2 consecutive cycles to force the IC into hiccup mode. Instead, the IC will run in a half frequency PWM mode leading to a larger output ripple.

## Overvoltage Protection

The overvoltage set point is set at 121% of the nominal output voltage set by the feedback resistors. In the case of an overvoltage event, the IC will attempt to bring the output voltage back into regulation by keeping the upper MOSFET turned off and the lower MOSFET turned on. If the overvoltage condition has been corrected and the output voltage returns to 110% of the nominal output voltage, both upper and lower MOSFETs will be turned off until the output voltage drops to the nominal voltage to start work in normal PWM switching.

## Over-Temperature Protection

The IC incorporates an over-temperature protection circuit that shuts the IC down when a die temperature of  $+160^{\circ}C$  is reached. Normal operation resumes when the die temperature drops below  $+145^{\circ}C$  through the initiation of a full soft-start cycle. During OTP shutdown, the IC consumes only  $100\mu A$  current. When the controller is disabled, thermal protection is inactive. This helps achieve a very low shutdown current of  $5\mu A$ .

## Feedback Loop Compensation

To adapt the different applications, the controller is designed with an externally compensated error amplifier. To make loop stable with wide input voltage and output current several design measures were taken.

First, The ramp signal applied to the PWM comparator is proportional to the input voltage provided at the VIN pin. This keeps the modulator gain constant with varying input voltages. Next, the load current proportional signal is derived from the voltage drop across the lower MOSFET during the PWM time interval and is subtracted from the amplified error signal on the comparator input. This creates an internal current control loop. The resistor  $R_{CS}$  connected to the ISEN pin sets the gain in the current feedback loop. The following expression estimates the required value of the current sense resistor depending on the maximum operating load current and the value of the MOSFET  $r_{DS(ON)}$  as shown in Equation 8.

$$R_{CS} \geq \frac{(I_{MAX})(r_{DS(ON)})}{30\mu A} \quad (EQ. 8)$$

Choosing  $R_{CS}$  to provide  $30\mu A$  of current to the current sample and hold circuitry is recommended but values down to  $2\mu A$  and up to  $100\mu A$  can be used.

Figure 32 shows the valley current mode buck converter circuit.

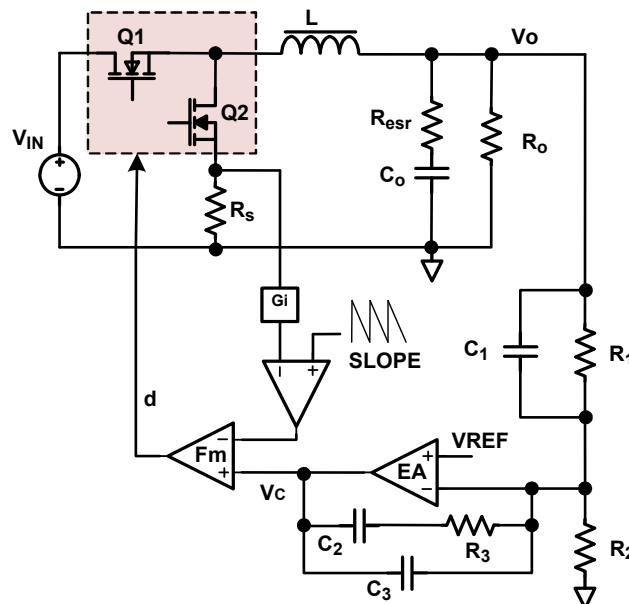


FIGURE 32. VALLEY CURRENT MODE BUCK CONVERTER CIRCUIT

In the current loop the control to output simplified transfer function is shown in [Equation 9](#).

$$\frac{\hat{V}_o}{\hat{V}_c} = \frac{R_o}{R_i \times K_d} \times \frac{1 + \frac{s}{\omega_z}}{\left(1 + \frac{s}{\omega_p}\right)\left(1 + \frac{s}{\omega_l}\right)} \quad (\text{EQ. 9})$$

Where:

$$K_d = 1 + \frac{R_o}{K_m \times R_i}$$

$$K_m = \frac{1}{(D - 0.5)R_i \times \frac{T}{L} + \frac{V_{sl}}{V_{in}}}$$

$$R_i = G_i \times R_s$$

$R_o$  is the load resistor

$C_o$  is the output capacitor

$L$  is the inductor

$R_s$  is the current sense resistor (the  $r_{DS(ON)}$  of low MOSFET)

$V_o$  is the output voltage

$T$  is the period of one switching cycle

$D$  is the duty cycle of upper MOSFET

$V_{sl}$  is the slope compensation voltage (peak voltage of the ramp)

$V_{in}$  is the input voltage of the buck

$V_c$  is the output of the error amplifier

$G_i$  is the gain of the current sensor

For ISL8117A:

$$V_{sl} = V_{in} \times 0.05$$

$$G_i = 8k/R_{cs}$$

Then the low frequency pole frequency is shown by [Equation 10](#).

$$\omega_p = 2\pi f_p = \frac{1}{C_o} \times \left( \frac{1}{R_o} + \frac{1}{K_m \times R_i} \right) \quad (\text{EQ. 10})$$

The high frequency pole frequency is shown by [Equation 11](#).

$$\omega_l = 2\pi f_l = \frac{K_m \times R_i}{L} \quad (\text{EQ. 11})$$

The output capacitor ESR ( $R_{esr}$ ) zero frequency is shown by [Equation 12](#).

$$\omega_z = 2\pi f_z = \frac{1}{C_o \times R_{esr}} \quad (\text{EQ. 12})$$

The output voltage is regulated by error amplifier EA. The EA compensation network parameters can be determined by compensating the current loop poles and zero so as to implement an ideal -20db/decade close loop gain with around 0.1 $f_{sw}$  crossover frequency.

If the crossover frequency  $f_c \ll f_l$ , a type 2 compensation network is enough to achieve the goal.

Since a strong slope compensation is used, the  $f_l$  is usually not too high but close to  $f_c$ . Thus, a type 3 amplifier is still needed.

To simplify the model, assuming  $C_3 \ll C_2$ , the type 3 EA amplifier transfer function is simplified to [Equation 13](#).

$$\frac{\hat{V}_c}{\hat{V}_o} = \frac{(1 + SR_3 C_2)(1 + SR_1 C_1)}{SR_1 C_2 (1 + SR_3 C_3)} \quad (\text{EQ. 13})$$

The transfer function has two poles and two zeros.

The first pole at the original at the frequency of  $f_{p1} = 1/2\pi R_1 C_2$ . This is the frequency where the impedance of  $R_1$  is equal to  $C_2$ .

The second pole is at the frequency of  $f_{p2} = 1/2\pi R_3 C_3$ .

The first zero is at the frequency of  $f_{z1} = 1/2\pi R_3 C_2$ .

The second zero is at the frequency of  $f_{z2} = 1/2\pi R_1 C_1$ .

To achieve ideal compensation, it is recommended to make  $f_{z1} = f_p$ ;  $f_{z2} = f_l$  and  $f_{p2} = f_z$  as shown in [Figure 33](#). The close loop transfer function is then simplified to [Equation 14](#).

$$\begin{aligned} G_{loop}(s) &= \frac{R_o}{R_i \times K_d} \times \frac{1 + \frac{s}{\omega_z}}{\left(1 + \frac{s}{\omega_p}\right)\left(1 + \frac{s}{\omega_l}\right)} \times \frac{(1 + SR_3 C_2)(1 + SR_1 C_1)}{SR_1 C_2 (1 + SR_3 C_3)} \\ &= \frac{R_o}{R_i \times K_d} \times \frac{1}{SR_1 C_2} \end{aligned} \quad (\text{EQ. 14})$$

The crossover frequency is shown by [Equation 15](#).

$$f_c = \frac{R_o}{R_i \times K_d} \times \frac{1}{2\pi R_1 C_2} \quad (\text{EQ. 15})$$

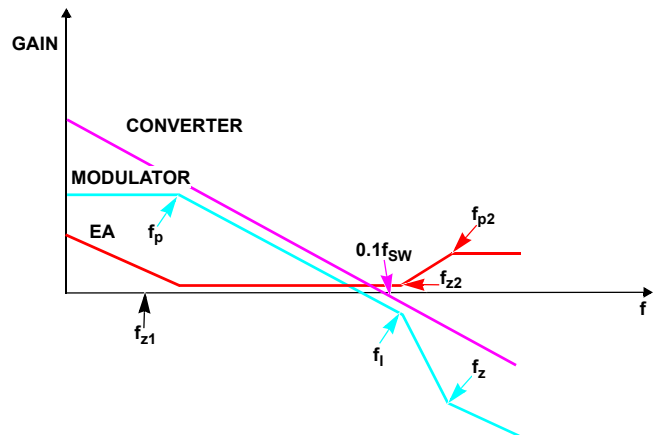


FIGURE 33. CROSSOVER FREQUENCY

Loop design example is shown in the following:

$$V_{IN} = 12V$$

$$V_{OUT} = 3.3V$$

$$I_{OUT} = 6A$$

$$f_{sw} = 300kHz$$

$$T = 3.3\mu s$$

$$D = V_{OUT}/V_{IN} = 0.275$$

$$L = 3.3\mu\text{H}$$

$$C_o = 200\mu\text{F}$$

$$R_o = V_{OUT}/I_{OUT} = 0.55\Omega$$

$$R_s = 14\text{m}\Omega$$

$$R_{CS} = 3\text{k}\Omega$$

Due to the use of ceramic capacitors, the output capacitor ESR ( $R_{ESR}$ ) zero frequency is very high and can be ignored.

$$\text{Then } V_{sl} = 0.6 \text{ and } R_i = 0.037$$

$$K_m = \frac{1}{(D - 0.5)R_i \times \frac{T}{L} + \frac{V_{sl}}{V_{in}}} = \frac{1}{(0.275 - 0.5)0.037 \times \frac{3.3\mu}{3.3\mu} + 0.05} = 24 \quad (\text{EQ. 16})$$

$$K_d = 1 + \frac{R_o}{K_m \times R_i} = 1 + \frac{0.55}{24 \times 0.037} = 1.62 \quad (\text{EQ. 17})$$

$$G_{dc} = \frac{R_o}{R_i \times K_d} = 9.18 \quad (\text{EQ. 18})$$

$$\omega_p = \frac{1}{C_o} \times \left( \frac{1}{R_o} + \frac{1}{K_m \times R_i} \right) = 14.7\text{k} \quad (\text{EQ. 19})$$

$$f_p = \frac{14.7\text{k}}{2\pi} = 2.34\text{k}$$

$$\omega_l = \frac{K_m \times R_i}{L} = \frac{24 \times 0.037}{3.3\mu} = 269\text{k} \quad (\text{EQ. 20})$$

$$f_l = \frac{269\text{k}}{2\pi} = 42.83\text{k}$$

To make 0.1fs crossover frequency and make the gain -20dB/decade use [Equation 21](#).

$$f_c = 0.1f_{SW} = 30\text{k} \quad (\text{EQ. 21})$$

If  $R_1 = 49.9\text{k}$ ,  $R_2 = 11\text{k}$ ,  $R_3 = 70\text{k}$ ,  $C_1 = 74\text{p}$  use [Equation 22](#).

$$C_2 = \frac{R_o}{R_i \times K_d} \times \frac{1}{2\pi R_1 f_c} = 0.97\text{n} \quad (\text{EQ. 22})$$

$$f_{z1} = \frac{1}{2\pi R_3 C_2} = 2.34\text{k}$$

$$f_{z2} = \frac{1}{2\pi R_1 C_1} = 42.83\text{k}$$

To suppress the switching frequency noise, one more pole  $f_{p2} = 1/2\pi R_3 C_3$  can be inserted.

The frequency of this pole should be  $f_c \ll f_{p2} \ll f_{SW}$

Select [Equation 23](#)

$$f_{p2} = \frac{1}{2\pi R_3 C_3} = 100\text{k} \quad (\text{EQ. 23})$$

$$\text{Then } C_3 = 23\text{p}$$

## Layout Guidelines

Careful attention to layout requirements is necessary for successful implementation of an ISL8117A based DC/DC converter. The ISL8117A switches at a very high frequency and therefore the switching times are very short. At these switching frequencies, even the shortest trace has significant impedance. Also, the peak gate drive current rises significantly in an extremely short time. Transition speed of the current from one device to another causes voltage spikes across the interconnecting impedances and parasitic circuit elements. These voltage spikes can degrade efficiency, generate EMI and increase device overvoltage stress and ringing. Careful component selection and proper PC board layout minimizes the magnitude of these voltage spikes.

There are three sets of critical components in a DC/DC converter using the ISL8117A: The controller, the switching power components and the small signal components. The switching power components are the most critical from a layout point of view because they switch a large amount of energy, which tends to generate a large amount of noise. The critical small signal components are those connected to sensitive nodes or those supplying critical bias currents. A multilayer printed circuit board is recommended.

## Layout Considerations

1. The input capacitors, upper FET, lower FET, inductor and output capacitor should be placed first. Isolate these power components on dedicated areas of the board with their ground terminals adjacent to one another. Place the input high frequency decoupling ceramic capacitors very close to the MOSFETs.
2. If signal components and the IC are placed in a separate area to the power train, it is recommend to use full ground planes in the internal layers with shared SGND and PGND to simplify the layout design. Otherwise, use separate ground planes for power ground and small signal ground. Connect the SGND and PGND together close to the IC. DO NOT connect them together anywhere else.
3. The loop formed by the input capacitor, the top FET and the bottom FET must be kept as small as possible.
4. Ensure the current paths from the input capacitor to the MOSFET, to the output inductor and the output capacitor are as short as possible with maximum allowable trace widths.
5. Place the PWM controller IC close to the lower FET. The LGATE connection should be short and wide. The IC can be best placed over a quiet ground area. Avoid switching ground loop currents in this area.
6. Place VCC5V bypass capacitor very close to the VCC5V pin of the IC and connect its ground to the PGND plane.
7. Place the gate drive components - optional BOOT diode and BOOT capacitors - together near the controller IC.
8. The output capacitors should be placed as close to the load as possible. Use short wide copper regions to connect output capacitors to load to avoid inductance and resistances.

9. Use copper filled polygons or wide short traces to connect the junction of upper FET, lower FET and output inductor. Also keep the PHASE node connection to the IC short. DO NOT unnecessarily oversize the copper islands for the PHASE node. Since the phase nodes are subjected to very high dv/dt voltages, the stray capacitor formed between these islands and the surrounding circuitry will tend to couple switching noise.
10. Route all high speed switching nodes away from the control circuitry.
11. Create a separate small analog ground plane near the IC. Connect the SGND pin to this plane. All small signal grounding paths including feedback resistors, current limit setting resistor, soft-starting capacitor and EN pull-down resistor should be connected to this SGND plane.
12. Separate the current sensing trace from the PHASE node connection.
13. Ensure the feedback connection to the output capacitor is short and direct.

## General PowerPAD Design Considerations

The following is an example of how to use vias to remove heat from the IC.

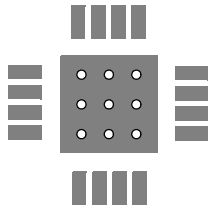


FIGURE 34. PCB VIA PATTERN

It is recommended to fill the thermal pad area with vias. A typical via array fills the thermal pad footprint such that their centers are 3x the radius apart from each other. Keep the vias small but not so small that their inside diameter prevents solder wicking through during reflow.

Connect all vias to the ground plane. It is important the vias have a low thermal resistance for efficient heat transfer. It is important to have a complete connection of the plated through-hole to each plane.

## Component Selection Guideline

### MOSFET Considerations

The logic level MOSFETs are chosen for optimum efficiency given the potentially wide input voltage range and output power requirement. Two N-Channel MOSFETs are used in the synchronous-rectified buck converters. These MOSFETs should be selected based upon  $r_{DS(ON)}$ , gate supply requirements and thermal management considerations.

Power dissipation includes two loss components: conduction loss and switching loss. These losses are distributed between the upper and lower MOSFETs according to duty cycle (see [Equations 24](#) and [25](#)). The conduction losses are the main component of power dissipation for the lower MOSFET. Only the

upper MOSFET has significant switching losses since the lower device turns on and off into near zero voltage. The equations assume linear voltage current transitions and do not model power loss due to the reverse recovery of the lower MOSFET's body diode.

$$P_{UPPER} = \frac{(I_O)^2 (r_{DS(ON)}) (V_{OUT})}{V_{IN}} + \frac{(I_O)(V_{IN})(t_{SW})(f_{SW})}{2} \quad (\text{EQ. 24})$$

$$P_{LOWER} = \frac{(I_O)^2 (r_{DS(ON)}) (V_{IN} - V_{OUT})}{V_{IN}} \quad (\text{EQ. 25})$$

A large gate-charge increases the switching time,  $t_{SW}$ , which increases the upper MOSFETs' switching losses. Ensure that both MOSFETs are within their maximum junction temperature at high ambient temperature by calculating the temperature rise according to package thermal resistance specifications.

### Output Inductor Selection

The PWM converter requires an output inductor. The output inductor is selected to meet the output voltage ripple requirements. The inductor value determines the converter's ripple current and the ripple voltage is a function of the ripple current and the output capacitor(s) ESR. The ripple voltage expression is given in the output capacitor selection section and the ripple current is approximated by [Equation 26](#):

$$\Delta I_L = \frac{(V_{IN} - V_{OUT})(V_{OUT})}{(f_{SW})(L)(V_{IN})} \quad (\text{EQ. 26})$$

The ripple current ratio is usually from 30% to 70% of the full output load.

### Output Capacitor Selection

The output capacitors for each output have unique requirements. In general, the output capacitors should be selected to meet the dynamic regulation requirements including ripple voltage and load transients. Selection of output capacitors is also dependent on the output inductor, so some inductor analysis is required to select the output capacitors.

One of the parameters limiting the converter's response to a load transient is the time required for the inductor current to slew to its new level. The ISL8117A will provide either 0% or maximum duty cycle in response to a load transient.

The response time is the time interval required to slew the inductor current from an initial current value to the load current level. During this interval, the difference between the inductor current and the transient current level must be supplied by the output capacitor(s). Minimizing the response time can minimize the output capacitance required. Also, if the load transient rise time is slower than the inductor response time, as in a hard drive or CD drive, it reduces the requirement on the output capacitor.

The maximum capacitor value required to provide the full, rising step, transient load current during the response time of the inductor is shown in [Equation 27](#):

$$C_{OUT} = \frac{(L_O)(I_{TRAN})^2}{2(V_{IN} - V_O)(DV_{OUT})} \quad (EQ. 27)$$

Where  $C_{OUT}$  is the output capacitor(s) required,  $L_O$  is the output inductor,  $I_{TRAN}$  is the transient load current step,  $V_{IN}$  is the input voltage,  $V_O$  is output voltage and  $DV_{OUT}$  is the drop in output voltage allowed during the load transient.

High frequency capacitors initially supply the transient current and slow the load rate of change seen by the bulk capacitors. The bulk filter capacitor values are generally determined by the ESR (Equivalent Series Resistance) and voltage rating requirements as well as actual capacitance requirements.

The output voltage ripple is due to the inductor ripple current and the ESR of the output capacitors as defined by [Equation 28](#):

$$V_{RIPPLE} = \Delta I_L (ESR) \quad (EQ. 28)$$

Where  $\Delta I_L$  is calculated in [Equation 26](#).

High frequency decoupling capacitors should be placed as close to the power pins of the load as physically possible. Be careful not to add inductance in the circuit board wiring that could cancel the usefulness of these low inductance components. Consult with the manufacturer of the load circuitry for specific decoupling requirements.

Use only specialized low-ESR capacitors intended for switching regulator applications for the bulk capacitors. In most cases, multiple small case electrolytic capacitors perform better than a single large case capacitor.

In conclusion, the output capacitors must meet the following criteria:

1. They must have sufficient bulk capacitance to sustain the output voltage during a load transient while the output inductor current is slewing to the value of the load transient.
2. The ESR must be sufficiently low to meet the desired output voltage ripple due to the output inductor current.

The recommended output capacitor value for the ISL8117A is between 100µF to 680µF, to meet the stability criteria with external compensation. Use of aluminum electrolytic (POSCAP) or tantalum type capacitors is recommended. Use of low ESR ceramic capacitors is possible with loop analysis to ensure stability.

## Input Capacitor Selection

The important parameters for the input capacitor(s) are the voltage rating and the RMS current rating. For reliable operation, select input capacitors with voltage and current ratings above the maximum input voltage and largest RMS current required by the circuit. The capacitor voltage rating should be at least 1.25x greater than the maximum input voltage and 1.5x is a conservative guideline. The  $AC_{RMS}$  input current varies with the load giving in [Equation 29](#):

$$I_{RMS} = \sqrt{DC - DC^2} \cdot I_O \quad (EQ. 29)$$

Where DC is duty cycle of the PWM.

The maximum RMS current supplied by the input capacitance occurs at  $V_{IN} = 2 \times V_{OUT}$ , DC = 50% as shown in [Equation 30](#):

$$I_{RMS} = \frac{1}{2} \times I_O \quad (EQ. 30)$$

Use a mix of input bypass capacitors to control the voltage ripple across the MOSFETs. Use ceramic capacitors for the high frequency decoupling and bulk capacitors to supply the RMS current. Small ceramic capacitors can be placed very close to the MOSFETs to suppress the voltage induced in the parasitic circuit impedances.

Solid tantalum capacitors can be used, but caution must be exercised with regard to the capacitor surge current rating. These capacitors must be capable of handling the surge current at power-up.

## Revision History

The revision history provided is for informational purposes only and is believed to be accurate, but not warranted. Please go to web to make sure you have the latest revision.

| DATE            | REVISION | CHANGE          |
|-----------------|----------|-----------------|
| August 31, 2015 | FN8752.0 | Initial Release |

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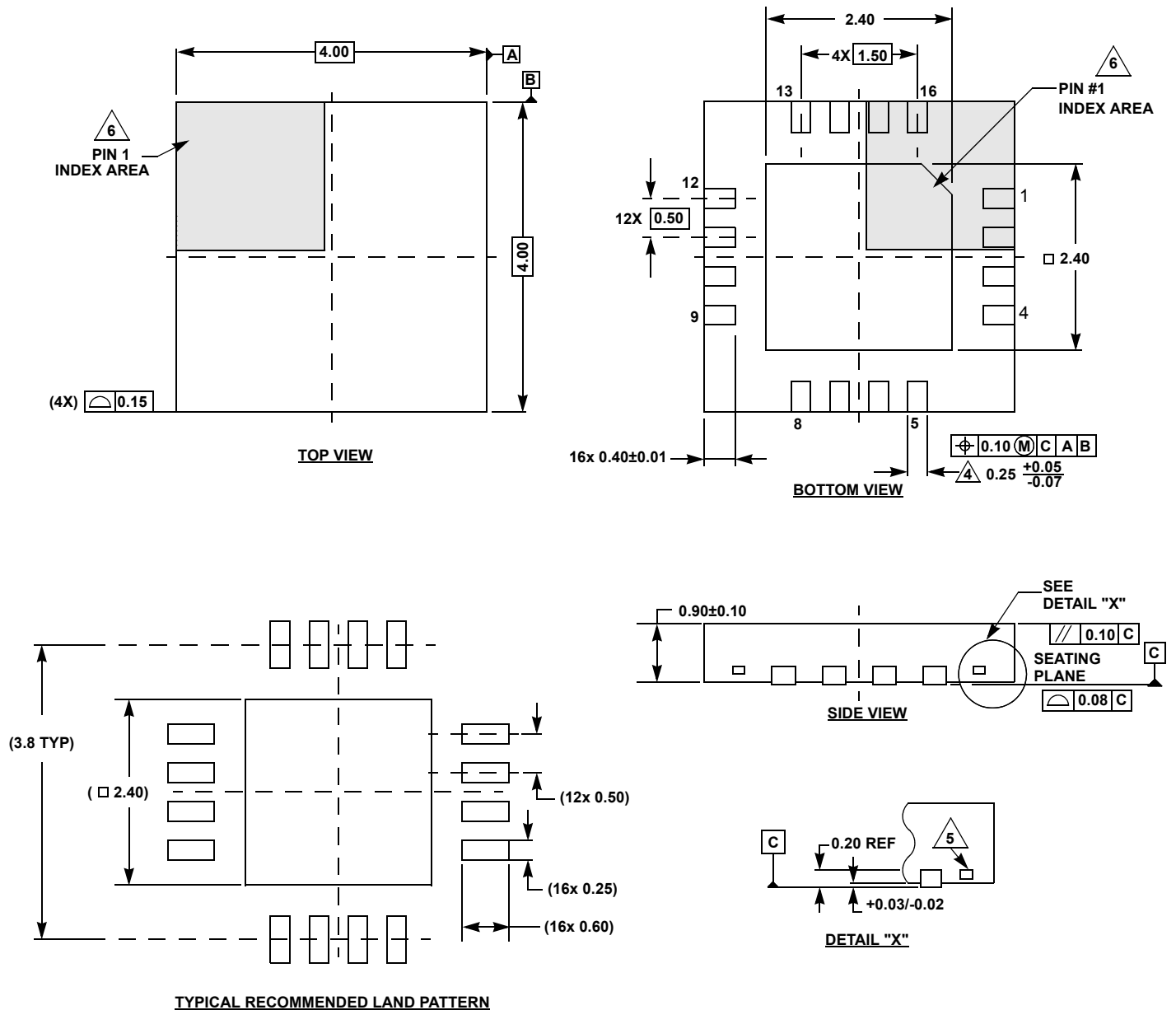
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# Package Outline Drawing

## L16.4x4A

16 LEAD QUAD FLAT NO-LEAD PLASTIC PACKAGE

Rev 3, 03/15



### NOTES:

- Dimensions are in millimeters.  
Dimensions in ( ) for Reference Only.
- Dimensioning and tolerancing conform to ASME Y14.5m-1994.
- Unless otherwise specified, tolerance: Decimal ± 0.05
- △4 Dimension applies to the metallized terminal and is measured between 0.15mm and 0.30mm from the terminal tip.
- △5 Tiebar shown (if present) is a non-functional feature.
- △6 The configuration of the pin #1 identifier is optional, but must be located within the zone indicated. The pin #1 identifier may be either a mold or mark feature.